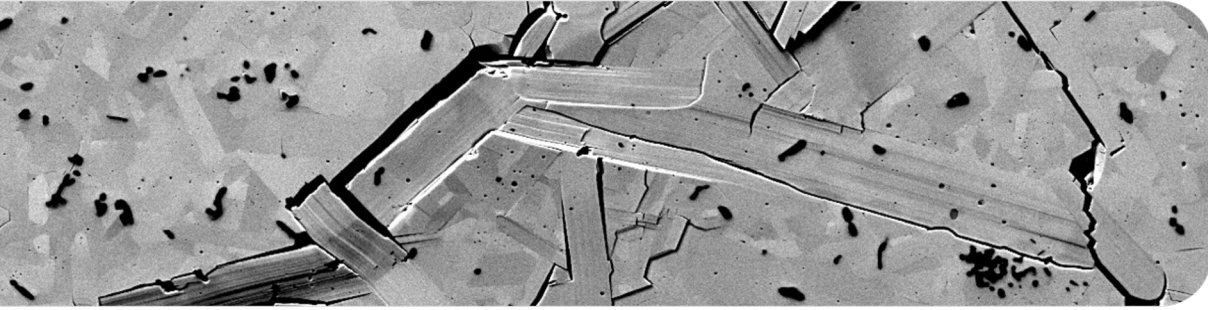




Crystal plasticity

Prof. Antoine GUITTON

Université de Lorraine, CNRS, Arts et Métiers Institute of Technology, LEM3, F-57000 Metz,
antoine.guitton@univ-Lorraine.fr



From craft to Science

Deformable / non-deformable

Solid

Non-deformable
(**Brittle**)



Deformable / non-deformable

Solid

Non-deformable
(**Brittle**)

Deformable
(**Ductile**)



Deformable / non-deformable

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Ig-Nobel 2017, Marc-Antoine FARDIN (ENS Lyon)

What ancient metalworkers learned?

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- Long before science explained how materials behave, ancient people already knew how to shape metal.
- Through practice and experience, they learned to control how metal responds to force, laying the foundation for what we now study as material behavior.

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❖ What they discovered?

- Bronze Age (around 3000 BCE)
 - People used copper and bronze to make tools and ornaments
 - They noticed:
 - ✓ Hitting metal made it stronger
 - ✓ Heating metal made it softer and easier to shape again.
- Iron Age (from around 1200 BCE)
 - Working with iron was harder, it needed more heat and stronger tools.
 - They learned:
 - ✓ Shaping hot iron helped make tools
 - ✓ Cooling quickly made them harder.
 - ✓ Reheating gently made them less fragile.



The so-called Mask of Agamemnon, discovered in Mycenae (Greece) in 1876, but crafted around the 16th century BCE. Made by cold-hammering a thin sheet of gold, it demonstrates early human control of irreversible metal deformation



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❖ What they knew without knowing?

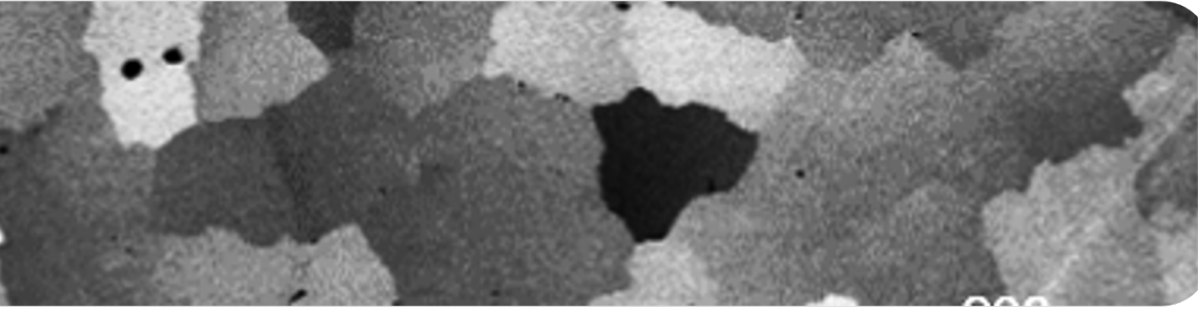
- Could tell the difference between:
 - Small changes that went back to normal
 - Bigger changes that stayed permanent
- They got very good at controlling how metal behaved.



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Macroscopic plasticity

The birth of elasticity (17th century)

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- Antiquity: only observations
 - Craftsmen in ancient Greece, Egypt, and Rome noticed that:
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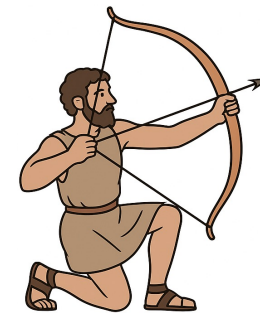
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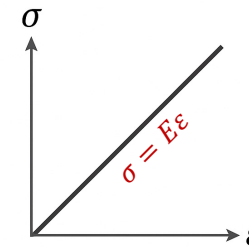
❖ Late 19th century:

$$\sigma = E\varepsilon$$

σ : stress; ε : strain; E : Young's modulus



**Observations
without theory**



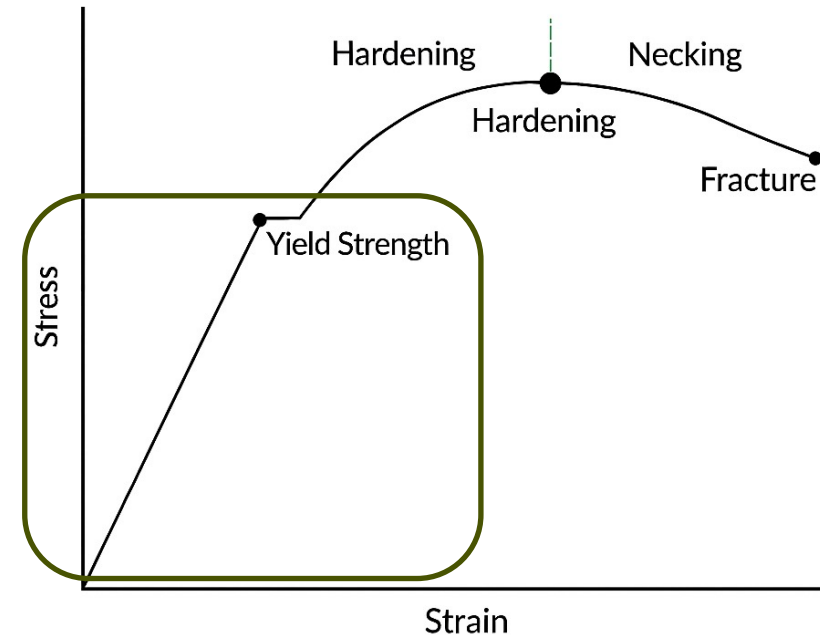
**Elasticity
becomes a law**

Essentials of elasticity

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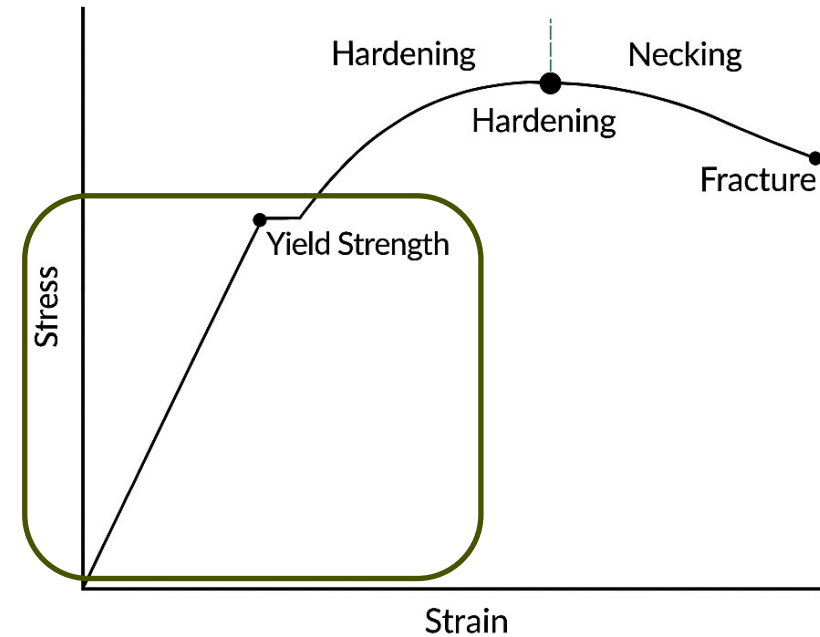
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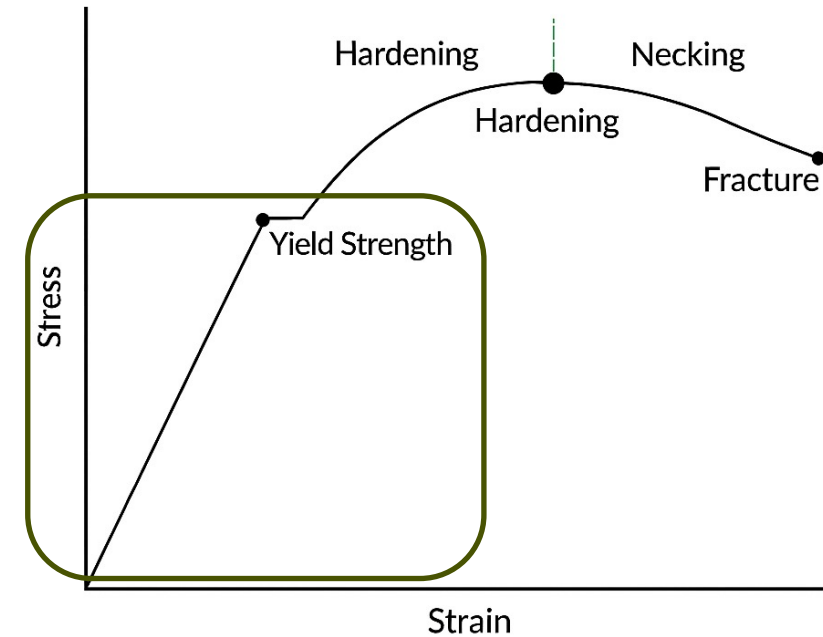
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❖ 3D generalization for isotropic materials:

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$$\lambda = \frac{Ev}{(1+\nu)(1-2\nu)}; \mu = \frac{E}{2(1+\nu)}; \sigma_{ij}: \text{stress tensor}; \varepsilon_{ij}: \text{strain tensor}$$



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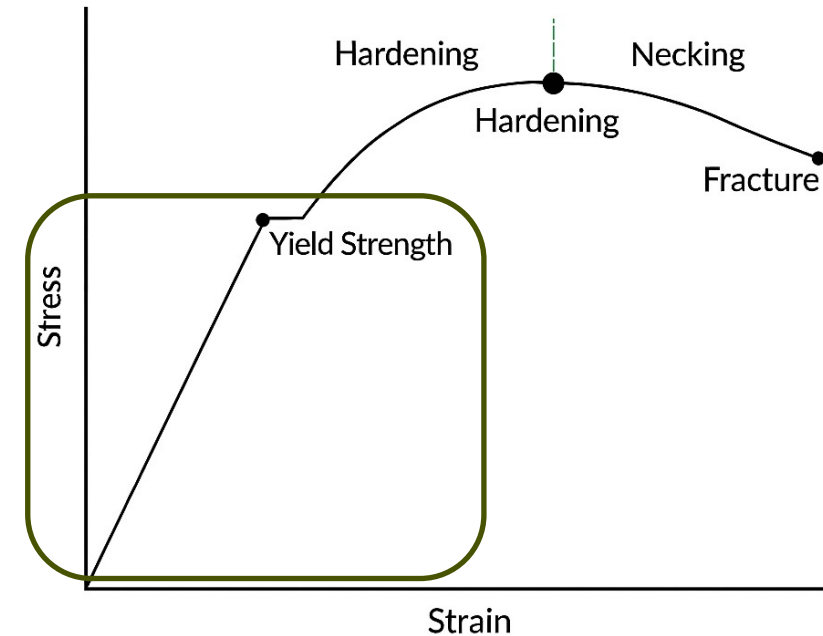
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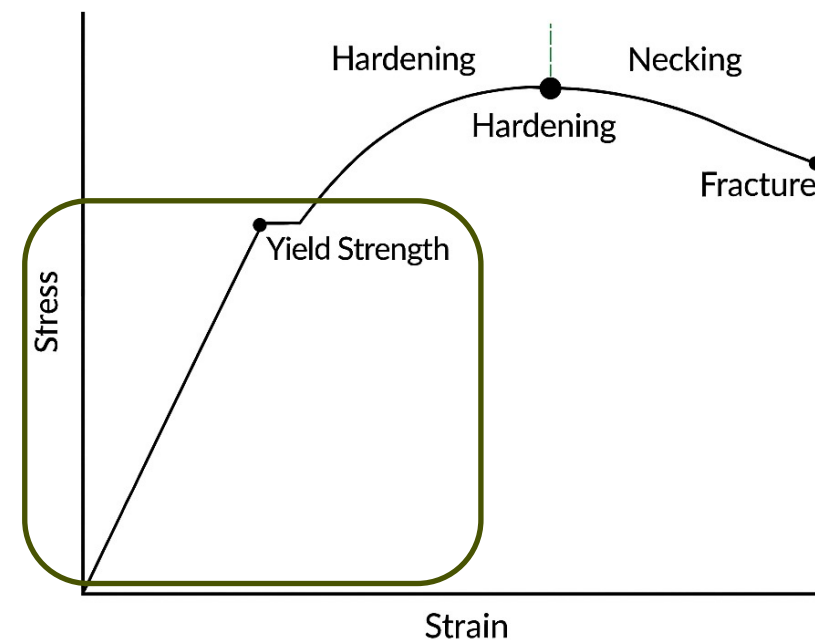
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$$\sigma = \mathbb{C} : \varepsilon \Leftrightarrow \sigma_{ij} = C_{ijkl} \varepsilon_{kl}$$

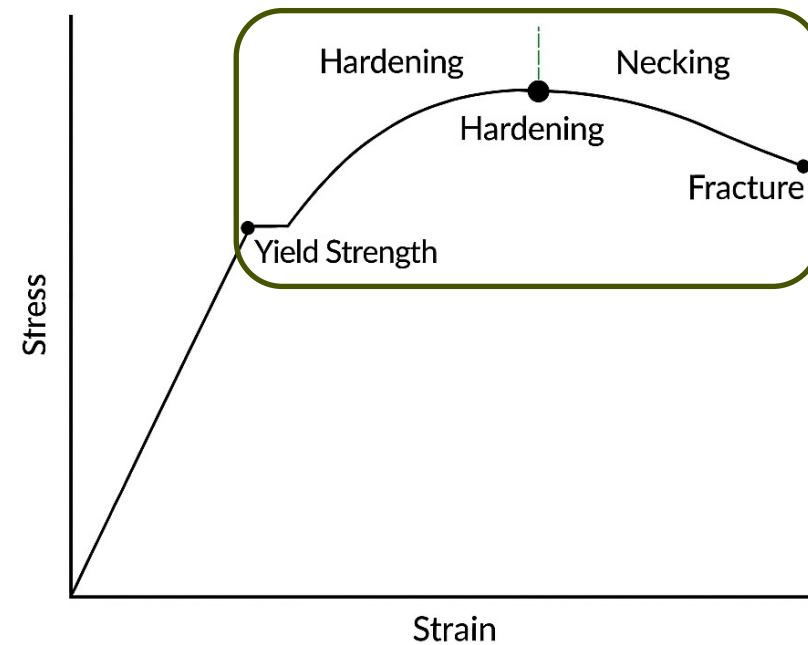
$\mathbb{C}, C_{ijkl}$: stiffness tensor



First empirical law of strain hardening

❖ Historical context:

- 1909: Paul Ludwik introduced the first empirical law describing the plastic behavior of ductile metals.
- At the time, most materials science focused on elasticity; Ludwik was among the first to address permanent deformation quantitatively.



First empirical law of strain hardening

❖ Historical context:

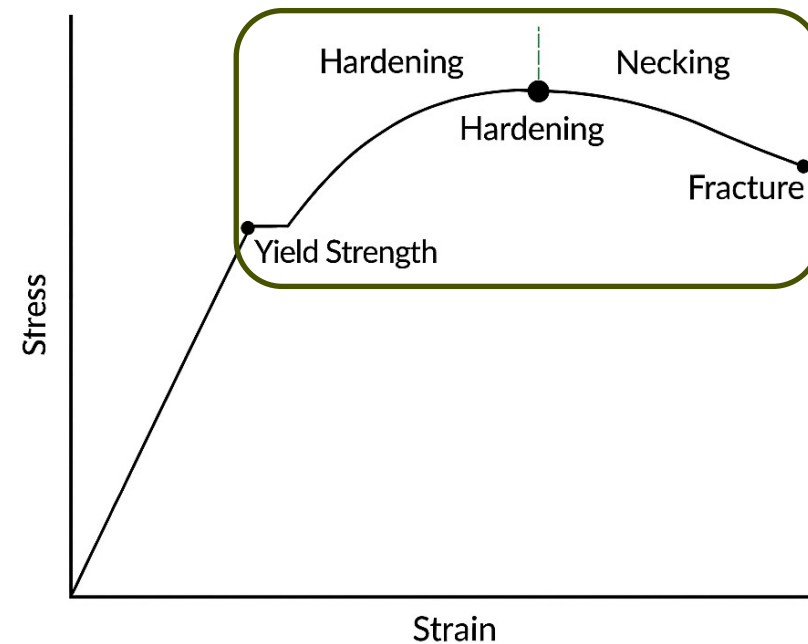
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❖ Ludwik's law (1909):

$$\sigma_T = \sigma_0 + K \varepsilon_T^n$$

$\sigma_T = \frac{F}{A_{inst}}$: true stress; $\varepsilon_T = \int_{L_0}^L \frac{dL}{L} - \varepsilon_e$: true plastic strain;
 K : strength coefficient; n : strain hardening exponent;
 σ_0 : yield stress (threshold for plastic flow)

- If $\sigma_0 = 0 \Rightarrow \sigma_T = K \varepsilon_T^n$ (Hollomon's law)



Visual evidence of crystal plasticity

❖ Late 19th – early 20th century:

- Mechanical testing of annealed polycrystalline metals (e.g., copper, brass) revealed surface markings after plastic deformation.

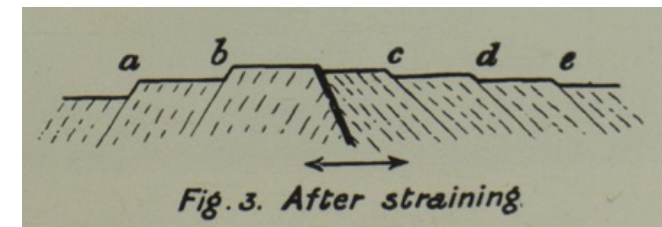
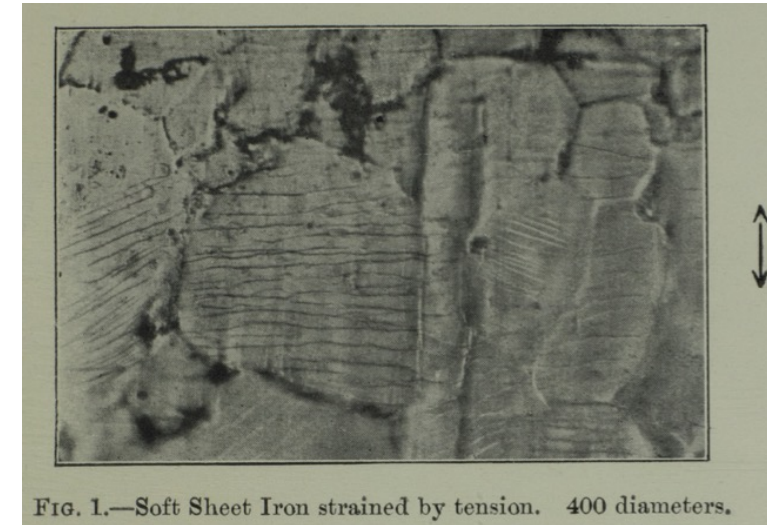
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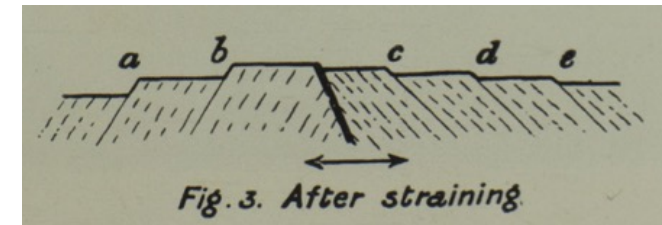
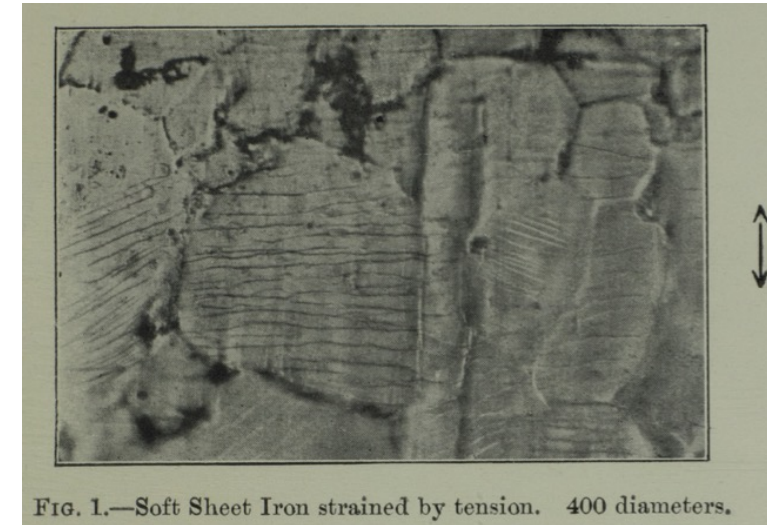
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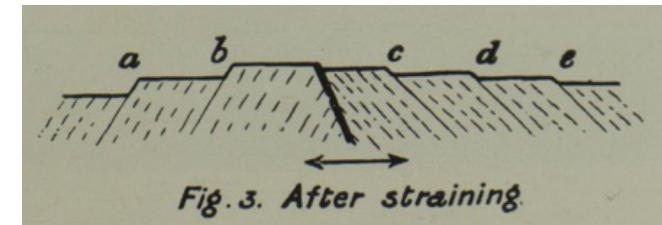
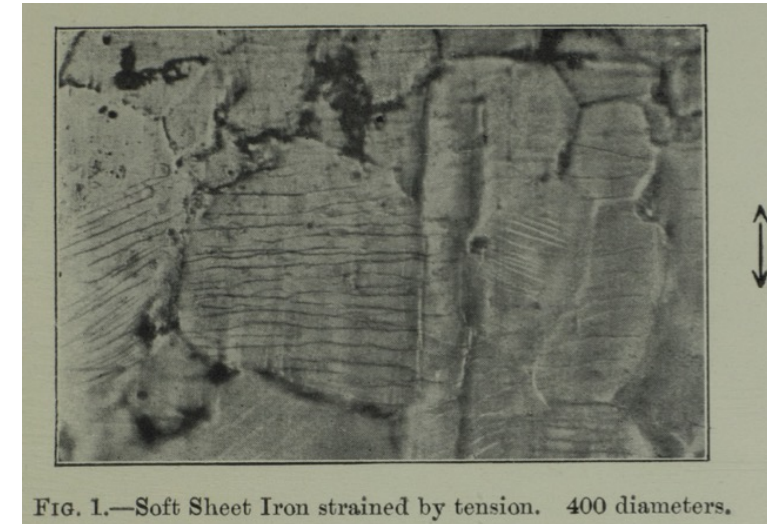
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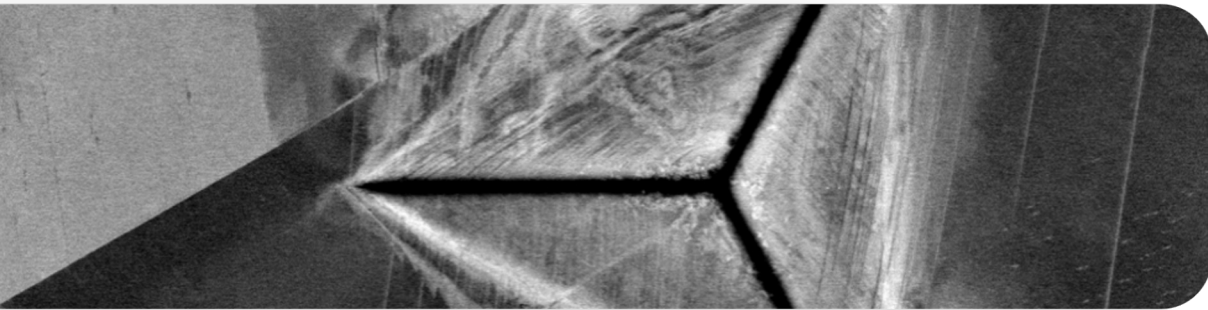
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➤ Main interpretation:

- Plastic deformation occurs by shear along discrete crystallographic planes, not homogeneously.
- Slip is localized and planar, consistent with the anisotropy of crystal structures.



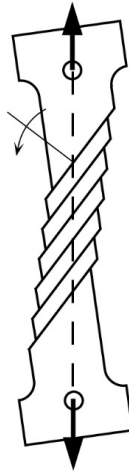
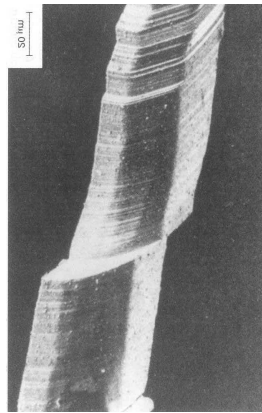


Crystal structure and slip systems

Explaining slip lines: the Schmid-Boas law

❖ Observations & hypotheses:

- Plastic deformation in single crystals occurs by slip along specific crystallographic planes and directions.
- The driving force for slip is the resolved shear stress acting on a given slip system.
- Slip initiates only when this resolved shear stress reaches a critical value, characteristic of the material.
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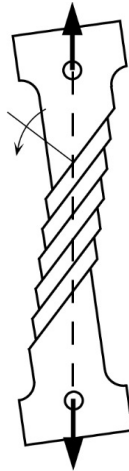
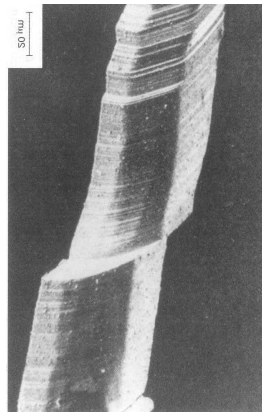
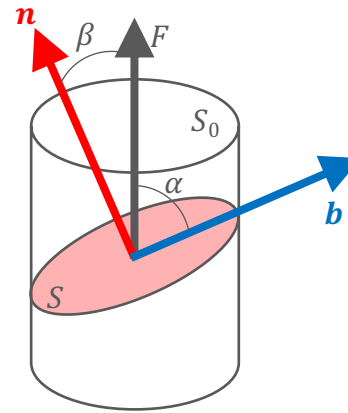
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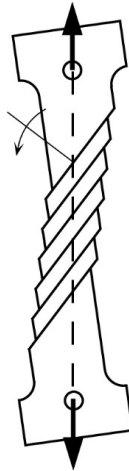
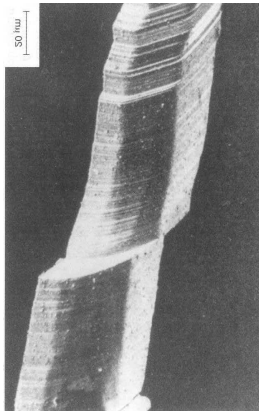
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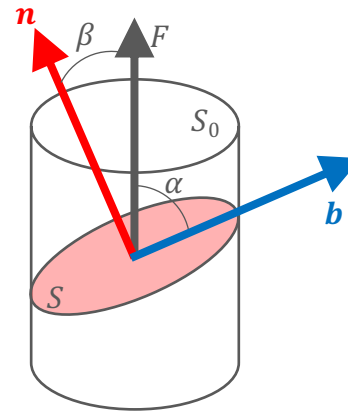


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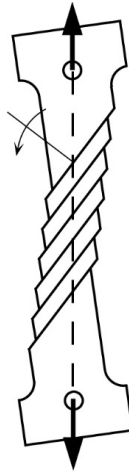
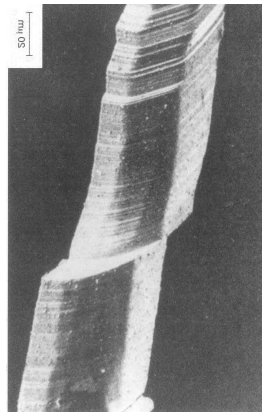
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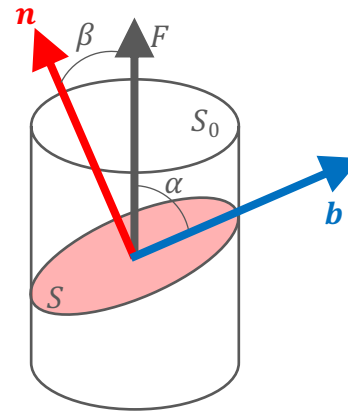
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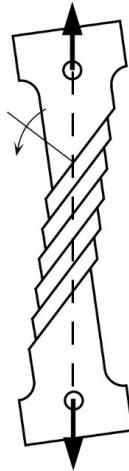
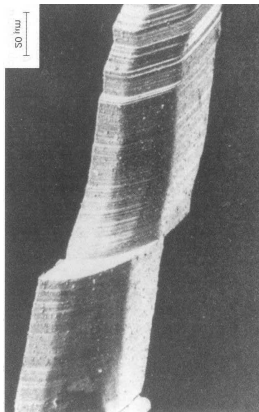
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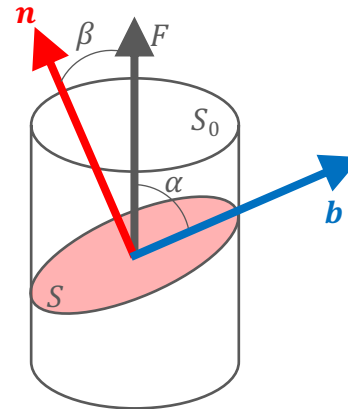
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❖ The projected shear stress (resolved shear stress) τ_{RSS} on the surface S is:

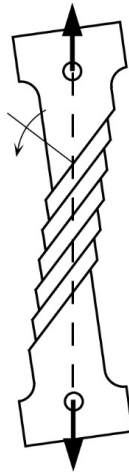
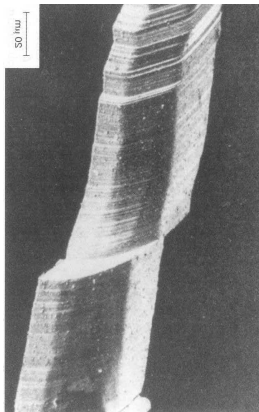
$$\tau_{RSS}^s = \frac{F_b}{S} = \frac{F \cos \alpha}{\frac{S_0}{\cos \beta}} = \frac{F}{S_0} \cos \alpha \cos \beta = \sigma \cos \alpha \cos \beta$$

$$\tau_{RSS}^s = \boldsymbol{\sigma} : \mathbf{b}_s \otimes \mathbf{n}_s$$

Explaining slip lines: the Schmid-Boas law

❖ Observations & hypotheses:

- Plastic deformation in single crystals occurs by slip along specific crystallographic planes and directions.
- The driving force for slip is the resolved shear stress acting on a given slip system.
- Slip initiates only when this resolved shear stress reaches a critical value, characteristic of the material.
- The normal stress on the slip plane has no effect on the onset of slip.
- Among all possible slip systems, the one with the highest resolved shear stress will be activated first.



❖ The normal applied stress:

$$\sigma = \frac{F}{S_0}$$

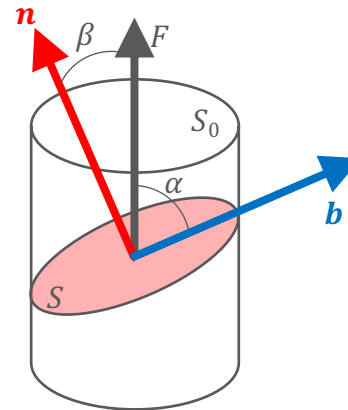
❖ The force F is projected onto the slip direction $\mathbf{b}$:

$$F_b = F \cos \alpha$$

❖ S is an ellipse of r and $\frac{r}{\cos \beta}$ as axes.

Its cross-section is:

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❖ The Schmid-Boas law:

✎ The $s = (\mathbf{b}, \mathbf{n})$ slip system is active $\Rightarrow \tau_{RSS}^s > \tau_{CRSS}^s$
 (τ_{CRSS}^s : critical resolved shear stress for the slip system s)

- Numerous materials do not follow the Schmid-Boas law...

How many slip systems does it take to make a crystal ductile?

36

❖ What we means

- A homogenous plastic deformation, *i.e.* a macroscopic plastic deformation that is continuous and compatible:
 - Homogeneous: the deformation is assumed to be uniform at the scale of the crystal (no local gradients of strain, no discontinuities between regions).
 - Plastic: it is produced solely by slip on slip systems, hence it is isochoric.
 - Compatible: it must preserve the continuity of the solid body (no voids, no overlaps)

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○ In math:

- Homogeneous deformation is described by a plastic strain tensor ϵ_{ij}^p that is constant throughout the crystal:

$$\epsilon^p = \begin{pmatrix} \epsilon_{11} & \epsilon_{12} & \epsilon_{13} \\ \epsilon_{21} & \epsilon_{22} & \epsilon_{23} \\ \epsilon_{31} & \epsilon_{32} & \epsilon_{33} \end{pmatrix} \rightarrow 9 \text{ components}$$

- The strain tensor is symmetric:

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- Pure slip is isochoric:

$$\text{tr } \epsilon^p = \epsilon_{11} + \epsilon_{22} + \epsilon_{33} = 0$$

⇒ which provides one scalar constraint.

⇒ ϵ^p has 5 components

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- ❖ The plastic strain rate can be written as a linear combination of Schmid tensors (one per slip system s : ($\mathbf{m}_s$: slip direction; $\mathbf{n}_s$: slip plane normal))

$$\dot{\epsilon}^p = \sum_s \dot{\gamma}_s \mathbf{S}_s; \mathbf{S}_s = \frac{1}{2}(\mathbf{m}_s \otimes \mathbf{n}_s + \mathbf{n}_s \otimes \mathbf{m}_s); \dot{\gamma}_s: \text{Shear strain rate on slip system } s$$

To be able to represent any admissible homogeneous plastic deformation, the set $\{\mathbf{S}_s\}$ must span the space of symmetric deviatoric tensors ⇒ $\text{rank}\{\mathbf{S}_s\} = 5$.

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↳ At least 5 linearly independent slip systems are required.

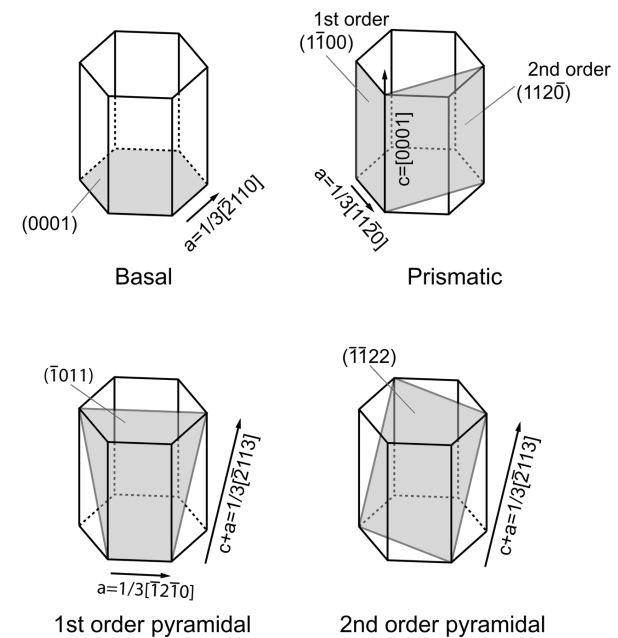
Slip systems and crystallographic structures

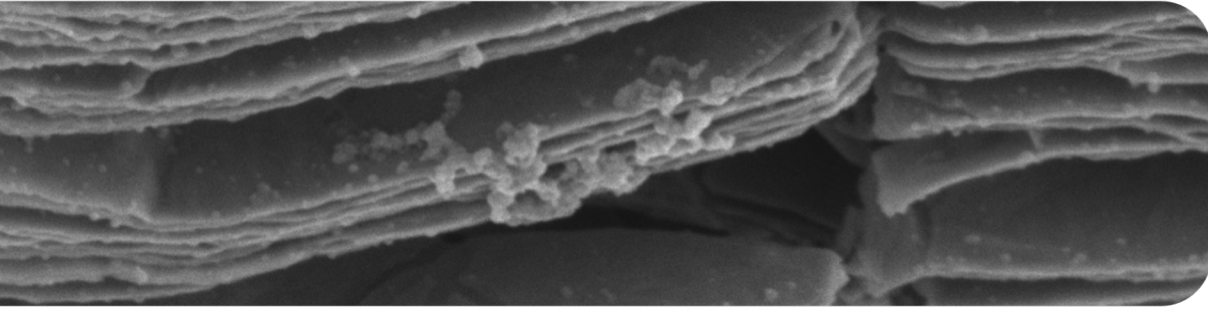
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- ❖ Slip occurs most easily in dense planes (highest atomic packing).
 - ⇒ These combinations provide the lowest energy pathways for atoms to move past one another.

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Structure	Slip direction (m_s)	Slip plane	Number of systems
FCC	$\langle 110 \rangle$	$\{111\}$	12
BCC	$\langle 111 \rangle$	$\{110\}$	12
		$\{112\}$	12
		$\{123\}$	24
HCP	$\langle 11\bar{2}0 \rangle = \langle a \rangle$	(0001)	3
	$\langle 11\bar{2}0 \rangle = \langle a \rangle$	$\{1\bar{1}00\}$	3
	$\langle 11\bar{2}0 \rangle = \langle a \rangle$	$\{\bar{1}01l\}$	6
	$\langle 11\bar{2}3 \rangle = \langle a + c \rangle$	$\{hkil\}$	12
	$[0001] = \langle c \rangle$	$\{1\bar{1}00\}$	3
	$[0001] = \langle c \rangle$	$\{11\bar{2}0\}$	3





The atomic model and dislocations

The atomic model

From the “plum pudding” model to Rutherford’s atom

❖ Before 1911:

- The dominant atomic model was the “plum pudding” model (J.J. Thomson, 1904):
 - Atoms were seen as a positively charged “pudding”,
 - with electrons embedded like “plums” inside —

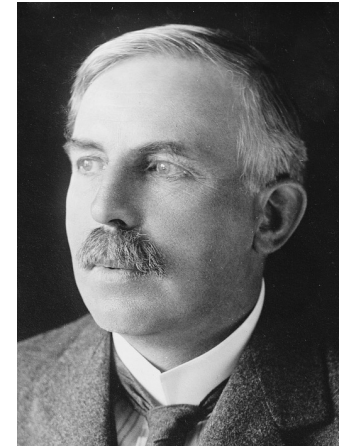
⇒ No structured nucleus, no empty space, no concept of atomic lattice.

❖ 1911: Rutherford’s gold foil experiment overturned this view:

- Most α -particles passed through gold foil, but a few were deflected at large angles.

⇒ Atoms are mostly empty space with a dense central nucleus.

“It was as if you fired a 15-inch shell at a piece of tissue paper and it came back and hit you.” (apocryphal)
- New atomic model:
 - Tiny, positively charged nucleus at the center,
 - Electrons orbiting at large distances.
 - Matter is composed of discrete, organized atoms



Ernest RUTHERFORD
(1871 – 1937) 🇬🇧
1 Nobel Prize (1908)

↪ The idea of a regular atomic lattice became physically meaningful only after Rutherford's atomic model and was firmly established through the development of X-ray crystallography. (Laue, 1912; Bragg, 1913)

First atomic model for the plasticity

❖ Observations & hypotheses:

- Crystals were known to deform plastically.
- Slip was observed to occur along specific crystallographic planes (slip planes).
- The atomic theory of matter is established, and crystals are described as periodic arrangements of atoms.

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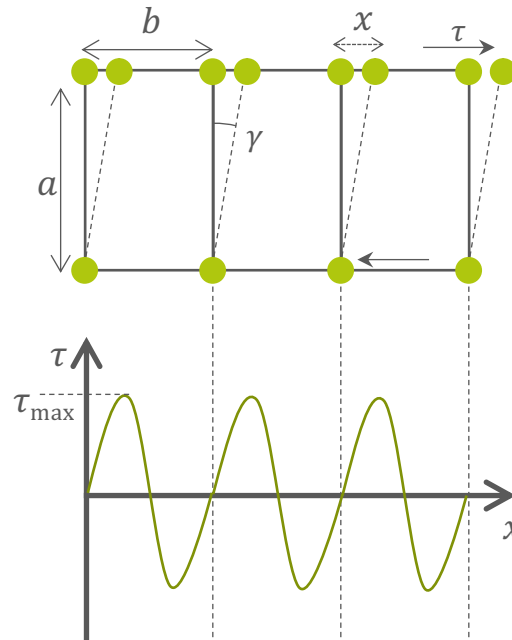
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$$\tau = \tau_{\max} \sin\left(\frac{2\pi}{b}x\right)$$

Atomic interactions were assumed to vary periodically with shear displacement, and approximated by a sinusoidal function.

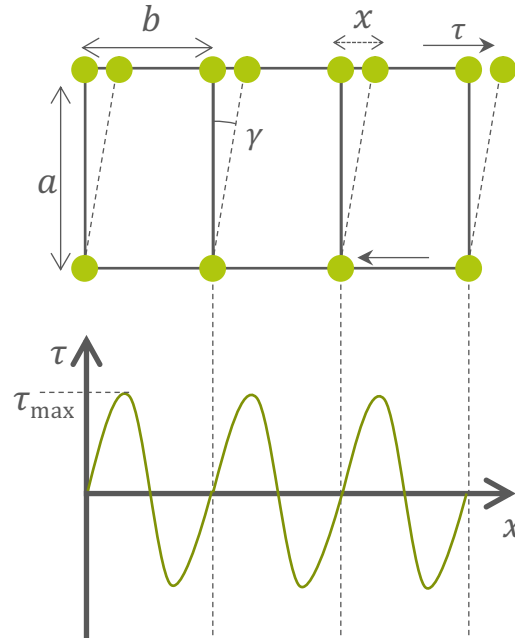


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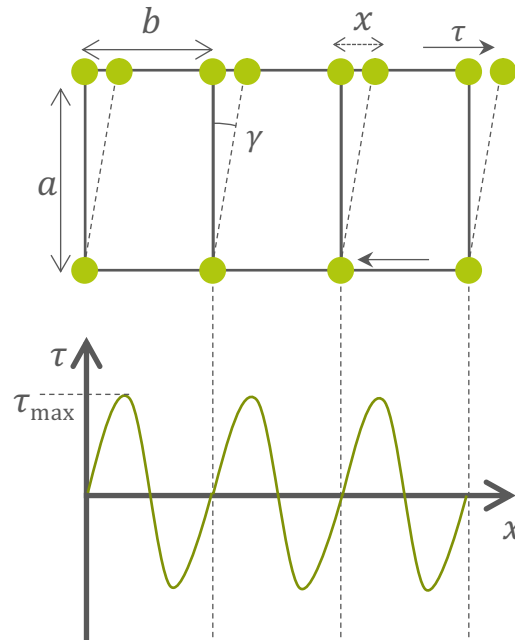
But $\tau = G\gamma$ (G : shear modulus)
 $\Rightarrow \tau = G \frac{x}{a}$

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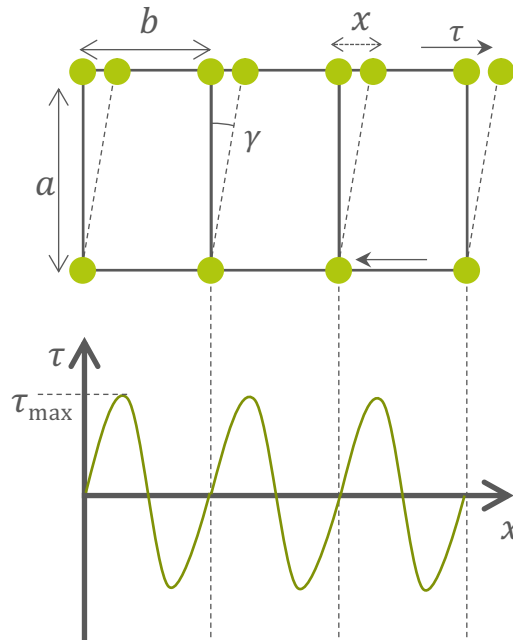
$$\Rightarrow \tau_{max} = \frac{G}{2\pi} \frac{b}{a} = \frac{G}{2\pi} \quad (\text{if } a = b) \Rightarrow \tau_{max} \sim \frac{G}{6}$$

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- ❖ To compare with R_e , τ_{max} must be converted to an equivalent one using plasticity criteria: (Tresca: $\tau^{Tr} = \frac{R_e}{2}$ or Von Mises: $\tau^{VM} = \frac{R_e}{\sqrt{3}}$)

Materials	R_e (MPa)	τ^{Tr} (MPa)	τ^{VM} (MPa)	τ_{max} (MPa)
Al (FCC)	10	5	5.8	26000
W (BCC)	750	375	433	160000
Mg (HCP)	25	12.5	14.4	16000

✋ In strong disagreement with experiments! **Plasticity cannot be explained by homogeneous shear.**

From Frenkel's paradox to dislocations

❖ G. I. Taylor (1934)

- Proposed that plastic shear could be explained by the motion of line defects in the crystal.
- Highlighted that such defects would allow slip at stresses far lower than Frenkel's homogeneous shear stress.
- Interpreted macroscopic plastic strain as the cumulative effect of many moving defects.

- Proposed a relation of the form:

$$\tau_c \propto G\delta\sqrt{\rho}$$

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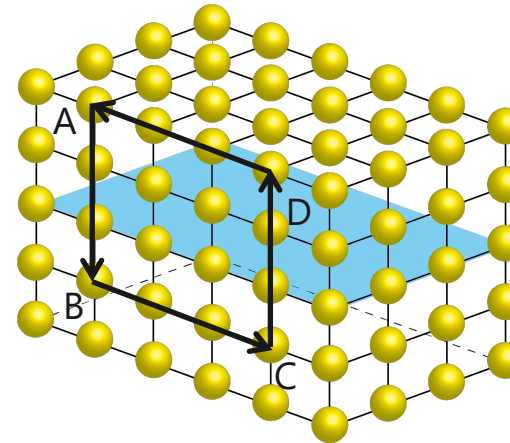
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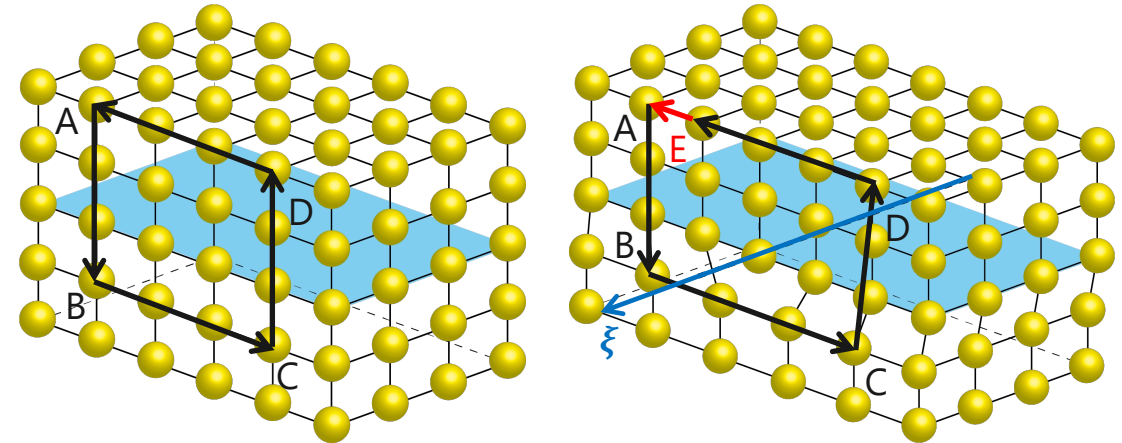
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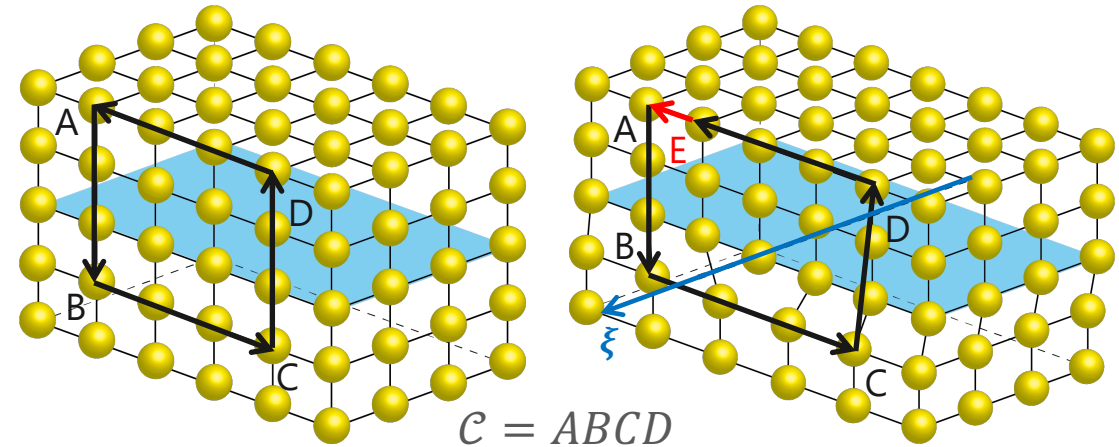
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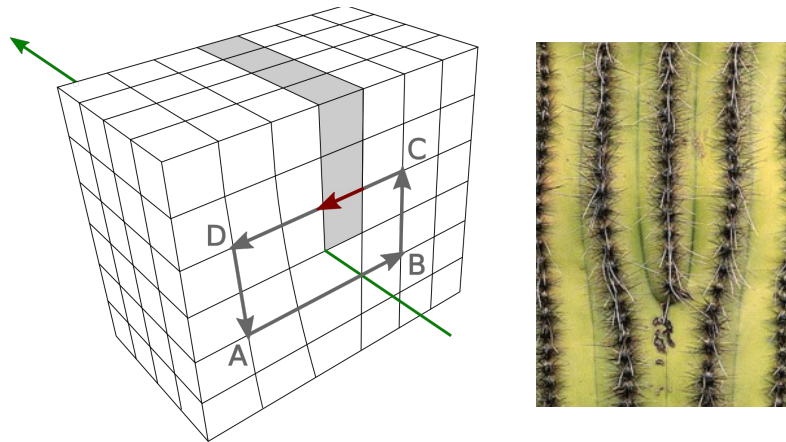


$$EA = d = b = \oint_C U^e dr \Rightarrow b_i = \oint_C \frac{\partial u_i}{\partial x_j} dx_j$$

Dislocation types

Edge

Characterized by an extra half-plane of atoms inserted into the lattice ($\mathbf{b} \perp \boldsymbol{\xi}$).

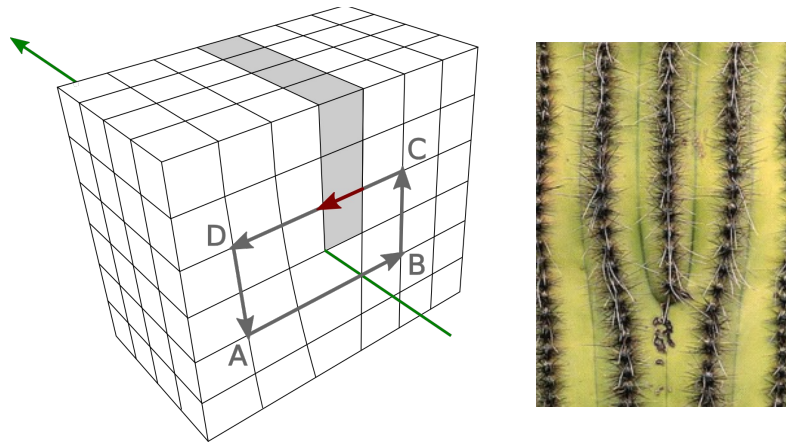


Symbol: $\perp$

Dislocation types

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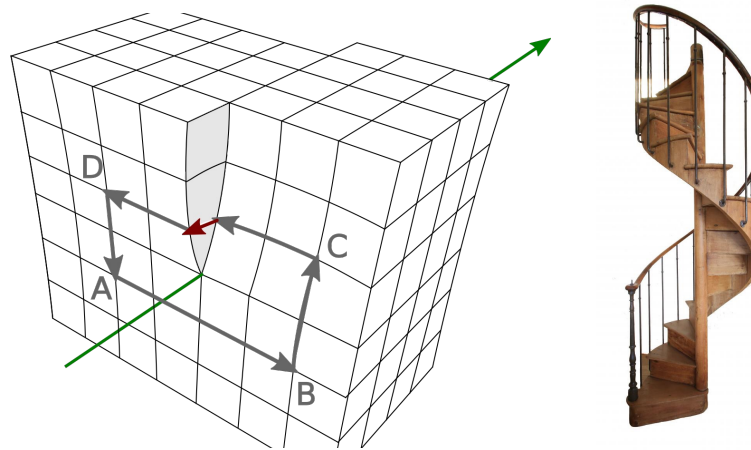
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Screw

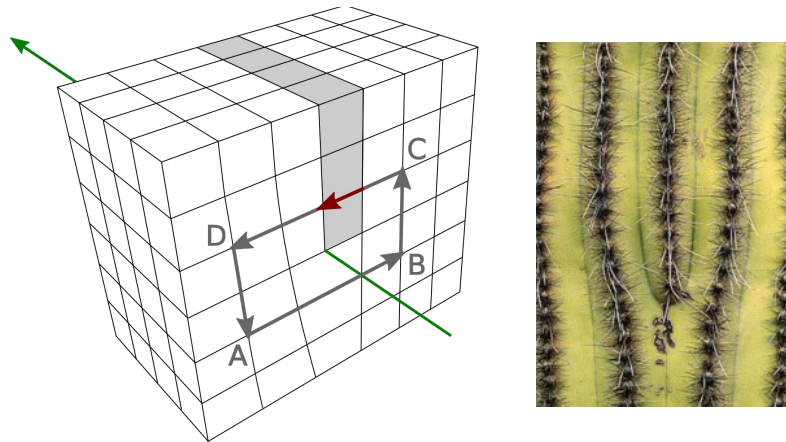
Results from a shear distortion, forming a helical ramp in the crystal lattice ($\mathbf{b} \parallel \boldsymbol{\xi}$).



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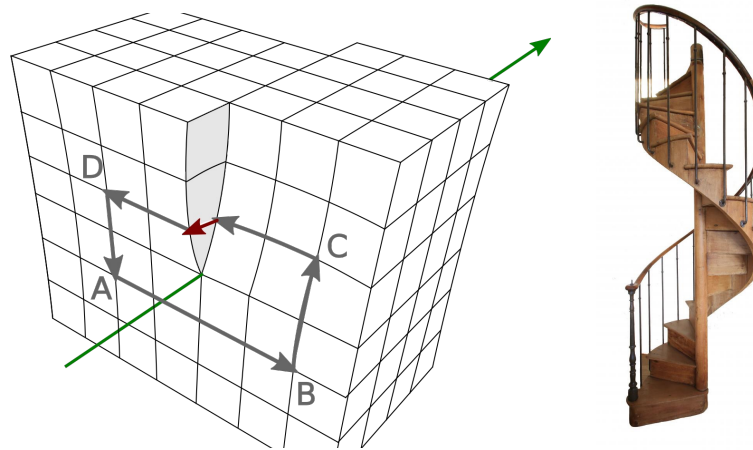
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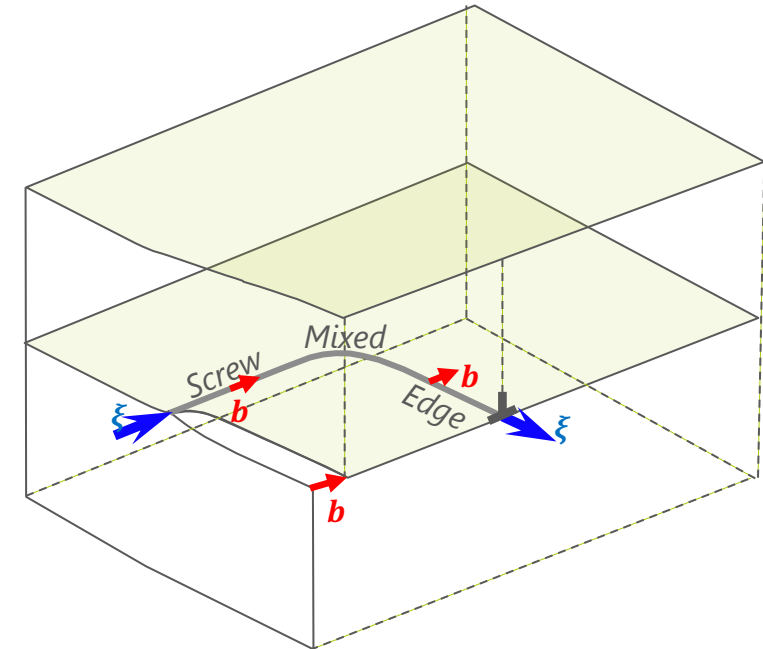
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Mixed

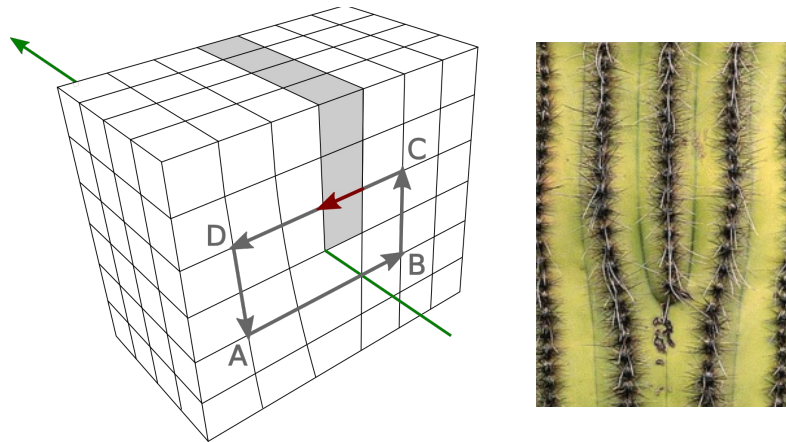
A combination of edge and screw dislocations ($b \angle \xi$).



Dislocation types

Edge

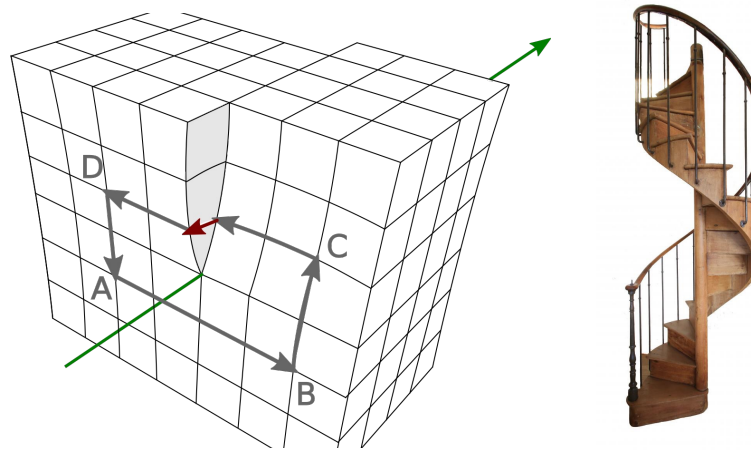
Characterized by an extra half-plane of atoms inserted into the lattice ($\mathbf{b} \perp \xi$).



Symbol: $\perp$

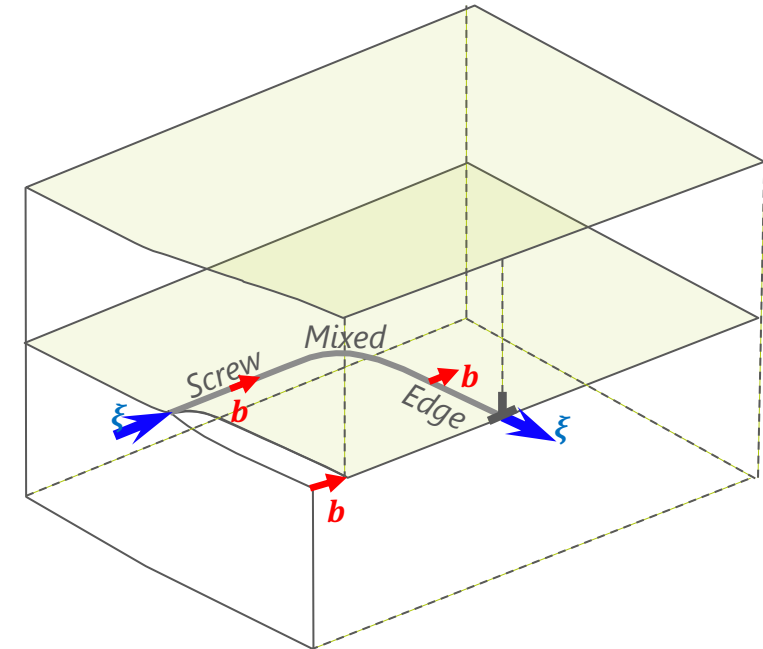
Screw

Results from a shear distortion, forming a helical ramp in the crystal lattice ($\mathbf{b} \parallel \xi$).



Mixed

A combination of edge and screw dislocations ($\mathbf{b} \angle \xi$).



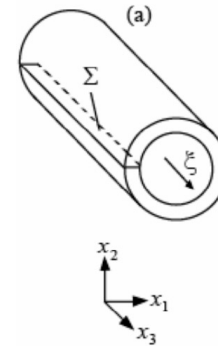
Dislocations are the carriers of plastic deformation in crystalline materials.

Volterra (1907): elastic foundation, read retrospectively

59

❖ Mathematical framework

- Isotropic continuum cylinder subjected to six cut-displace-reweld operations
- Continuum mechanics framework: no reference to crystals or plasticity



Volterra (1907): elastic foundation, read retrospectively

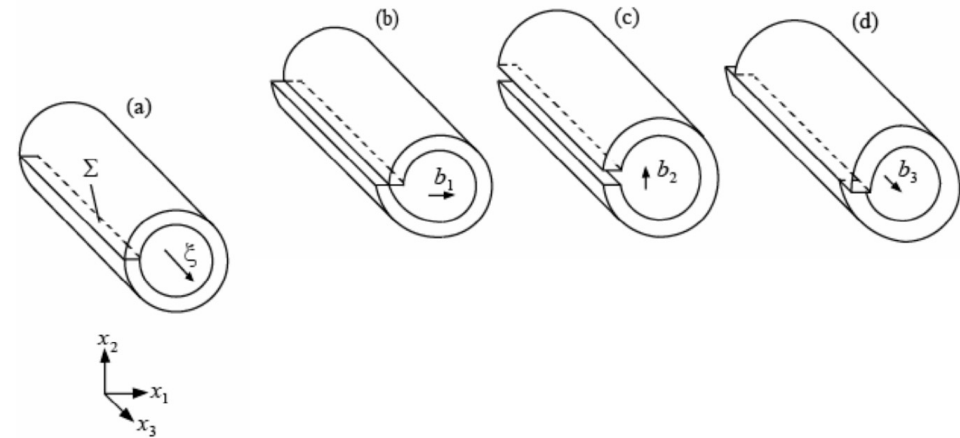
60

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❖ Six configurations

- Translations (b_1, b_2, b_3): edge dislocations (b) and (c); screw dislocation (d)



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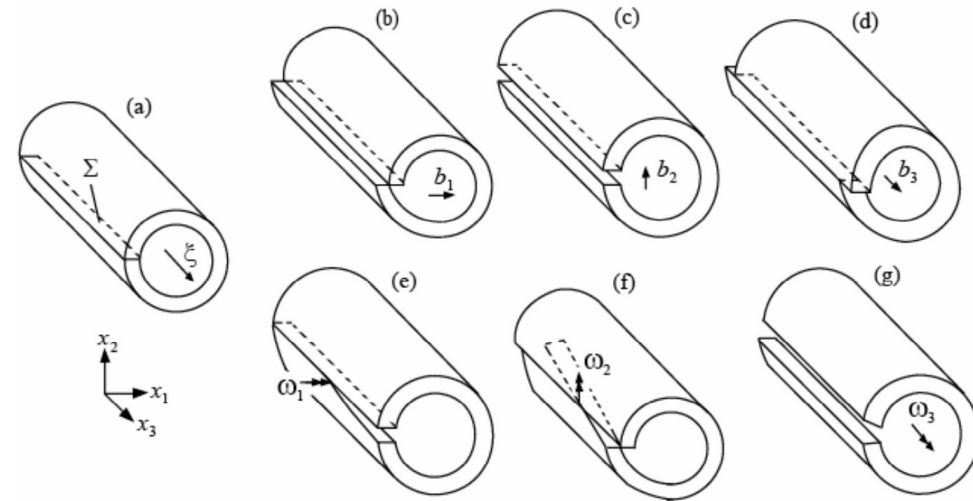
61

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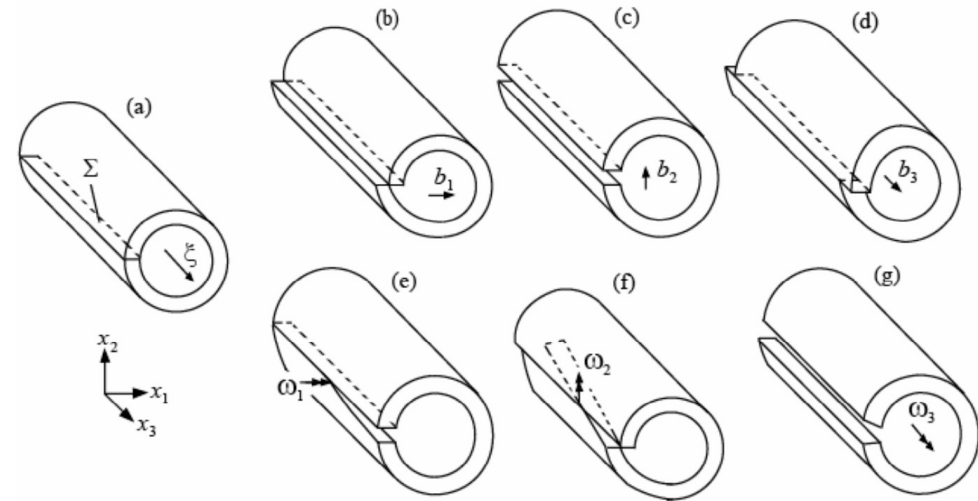
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❖ Retrospective reading

- Connection to crystal plasticity not established by Volterra; unnoticed until after 1934
- Physical postulation by Taylor, Orowan and Polanyi (1934); geometric formalization by Burgers (1939)
- Dislocation types formally defined by Frank (1949)



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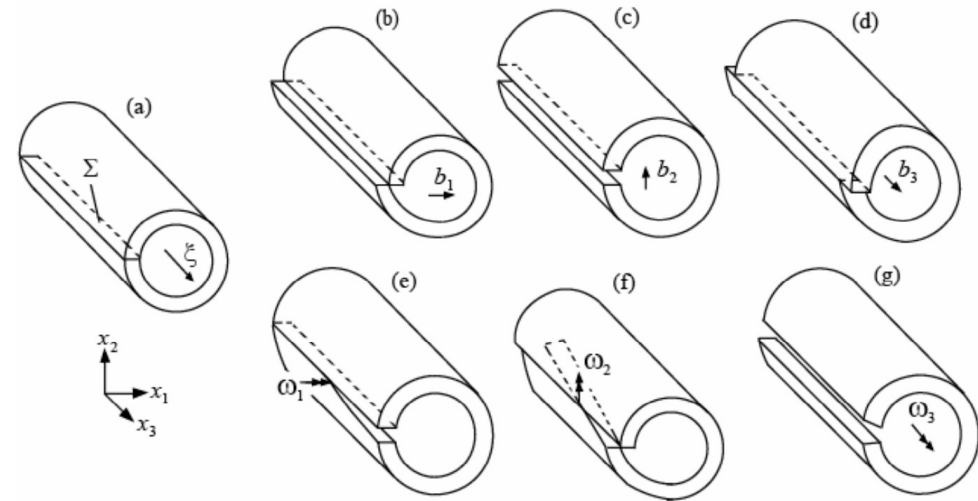
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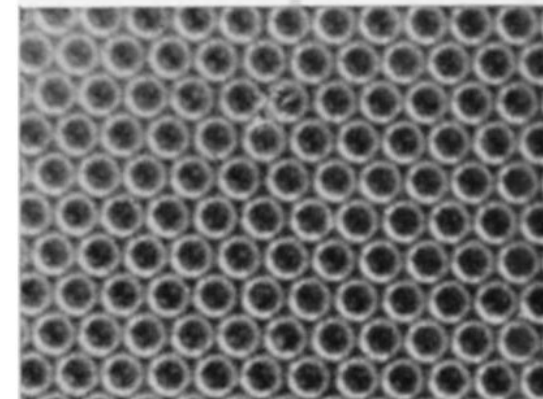
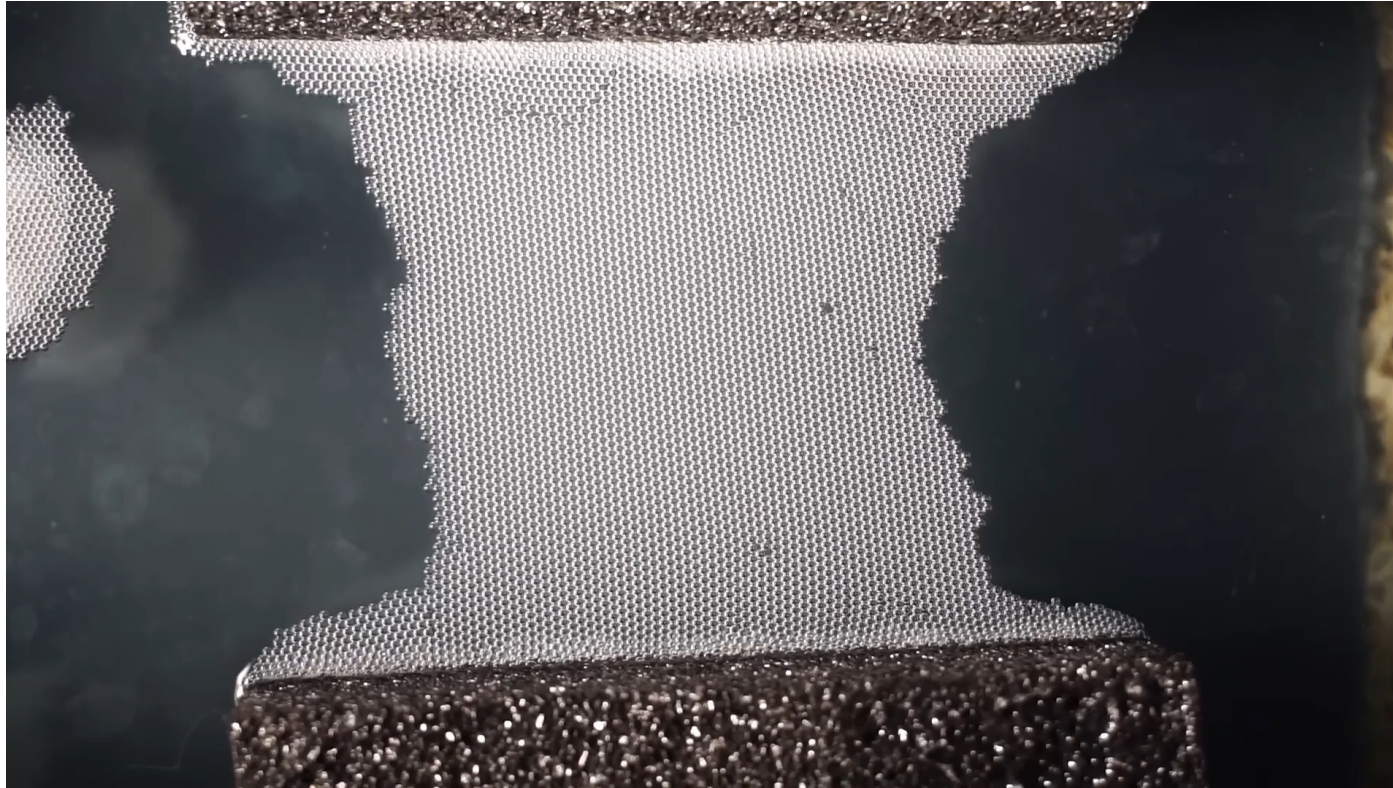
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- Physical postulation by Taylor, Orowan and Polanyi (1934); geometric formalization by Burgers (1939)
- Dislocation types formally defined by Frank (1949)
- Retrospective connection to Volterra's work consolidated in the 1950s; term "Volterra dislocation" introduced then.



↳ All six fundamental defect configurations had been mathematically predicted by 1907;
30 years before dislocations were postulated to explain plastic deformation in crystals!

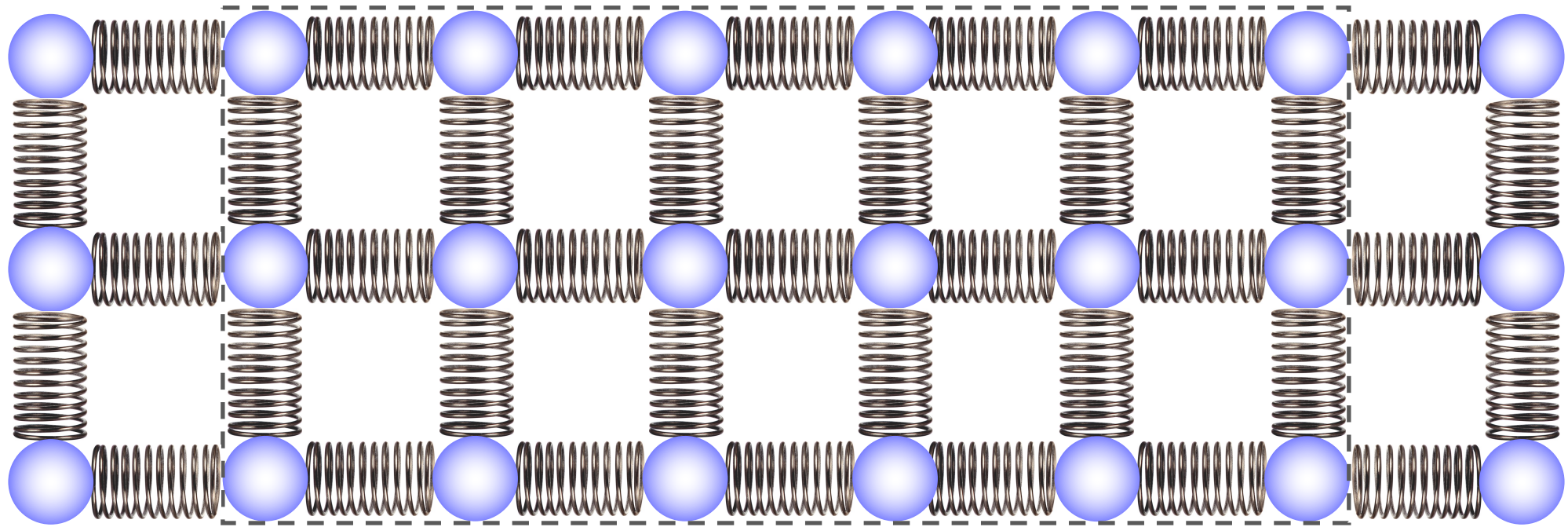
Dislocations are the carriers of plastic deformation

64



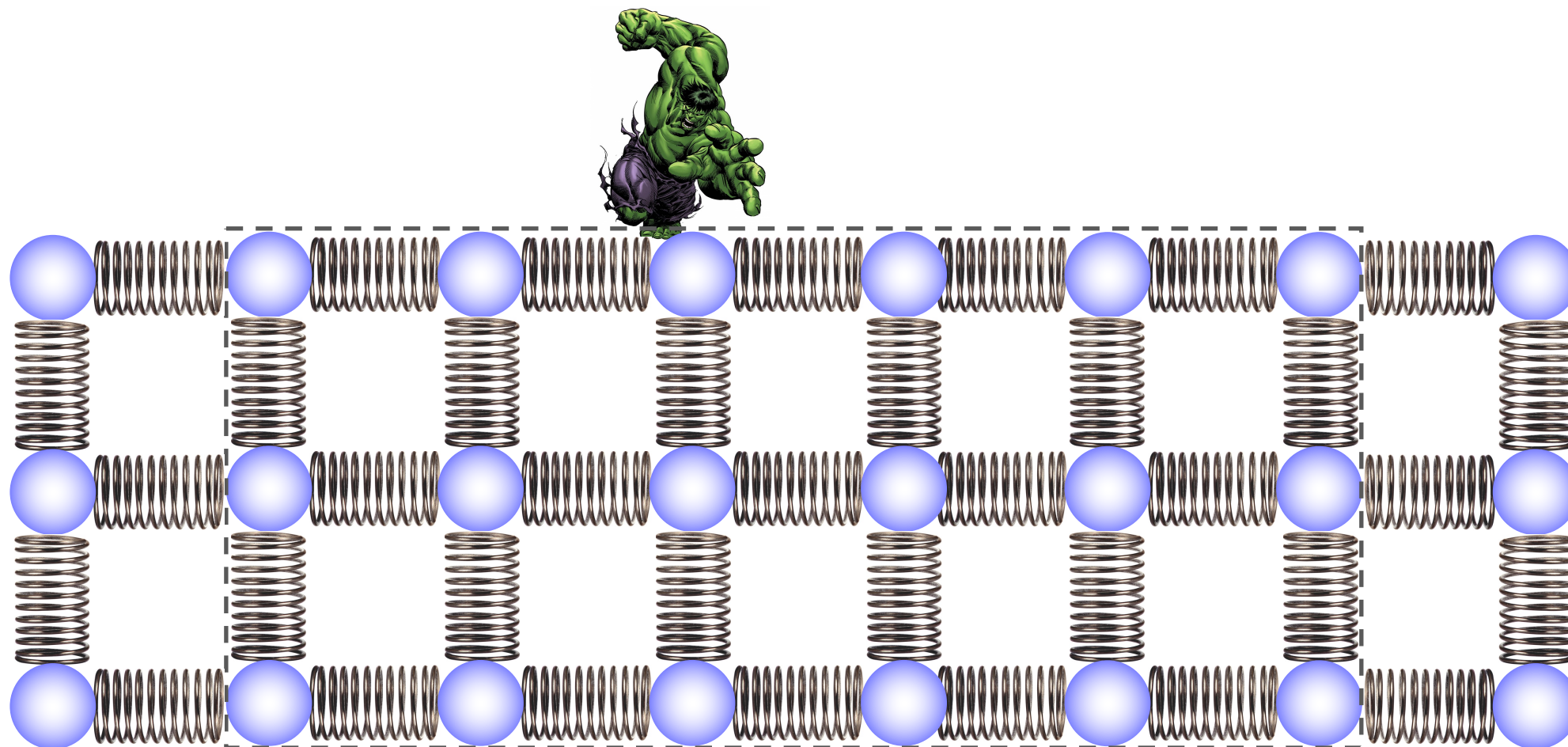
Dislocations are the carriers of plastic deformation

Initial size of the structure $L \times l \times h$



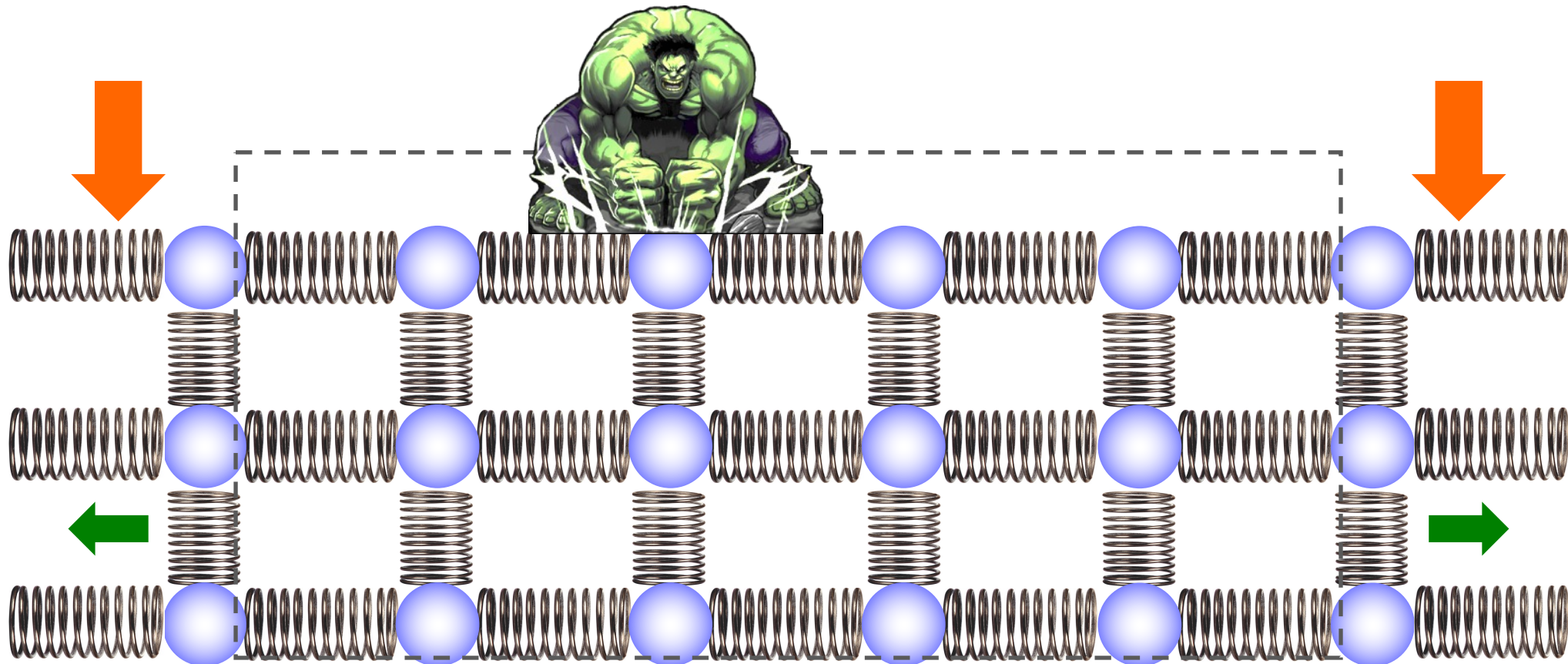
Dislocations are the carriers of plastic deformation

Application of a vertical load



Dislocations are the carriers of plastic deformation

Under the load, the vertical springs are compressed and the horizontal ones are stretched.

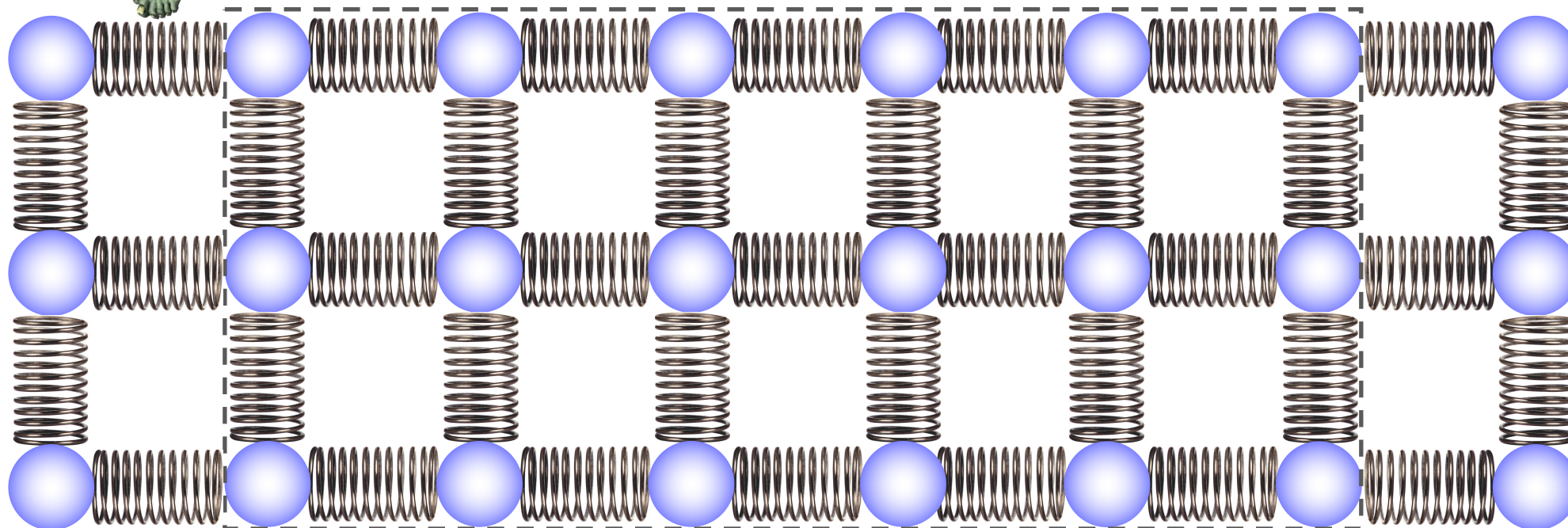


Dislocations are the carriers of plastic deformation

When the load is removed, the structure returns to its original dimensions.

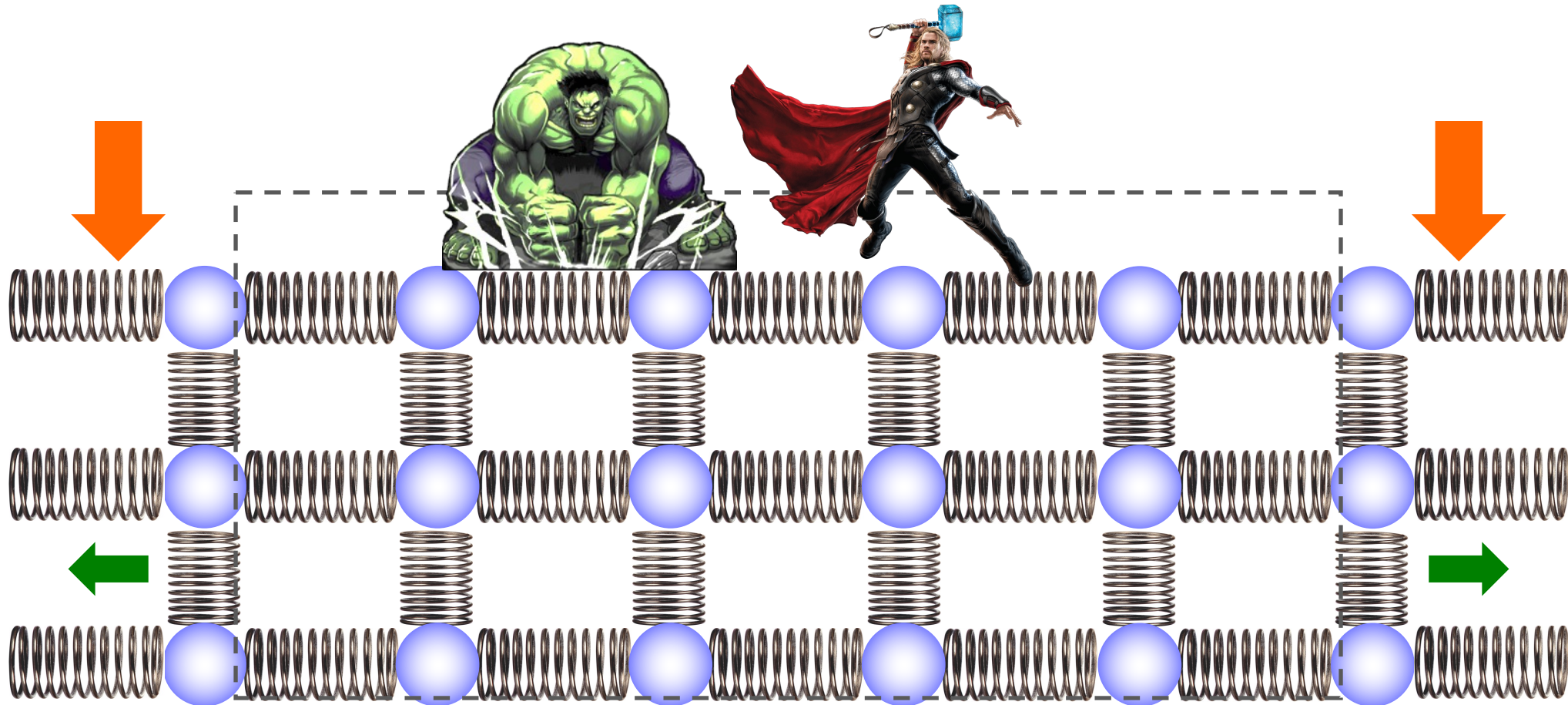


Reversible deformation
=
Elastic deformation



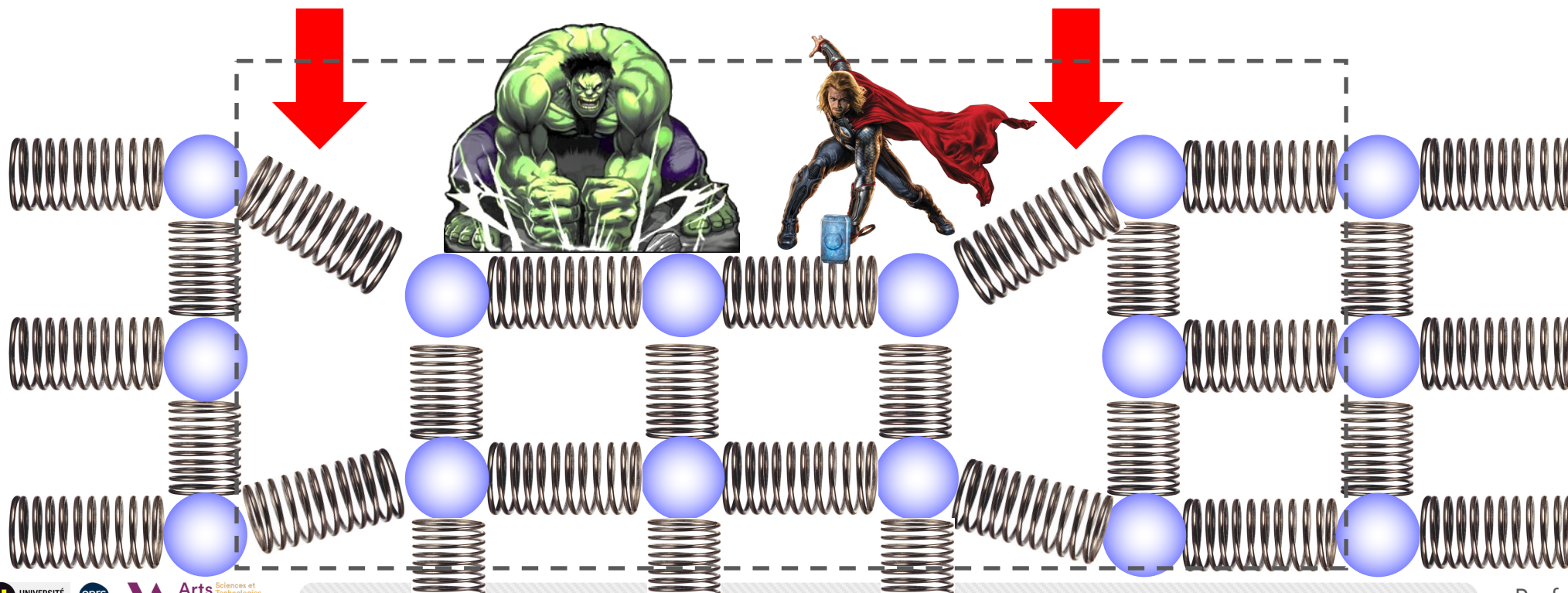
Dislocations are the carriers of plastic deformation

Under the load, the vertical springs are compressed and the horizontal ones are stretched.
A higher load is applied.



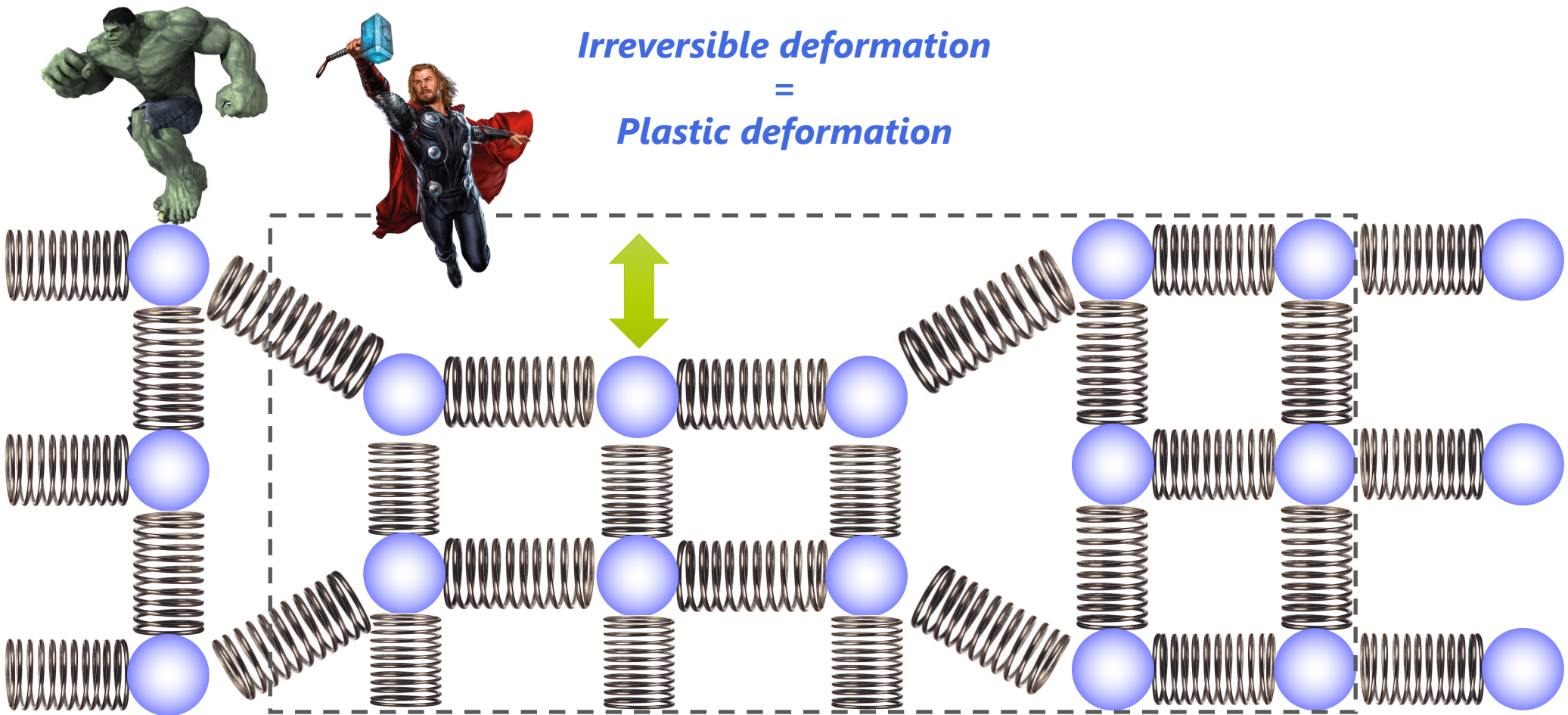
Dislocations are the carriers of plastic deformation

Under the load, the vertical springs are compressed and the horizontal ones are stretched.
Some springs are broken.



Dislocations are the carriers of plastic deformation

Since some springs are broken, the structure does not return to its original shape.



Dislocations are the carriers of plastic deformation

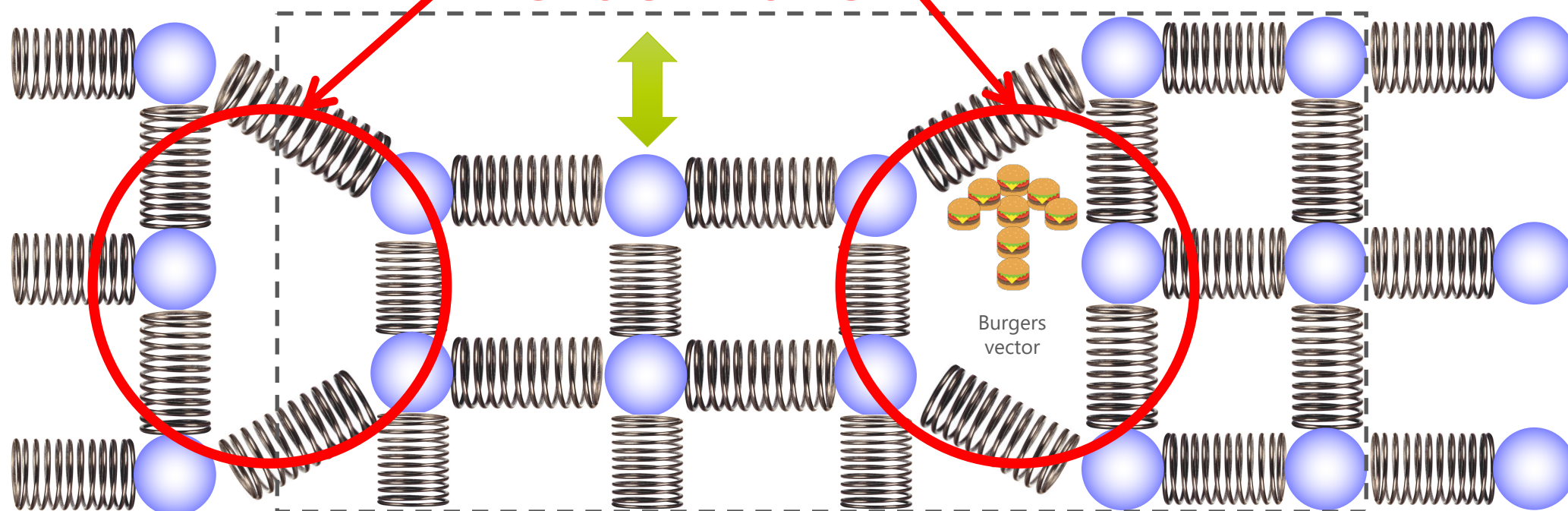
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Irreversible deformation

=

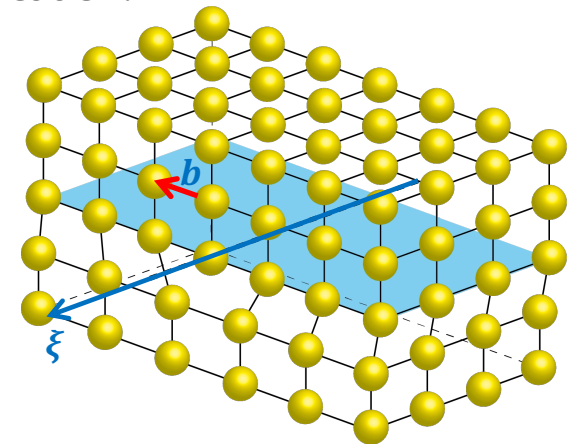
Plastic deformation

DISLOCATIONS



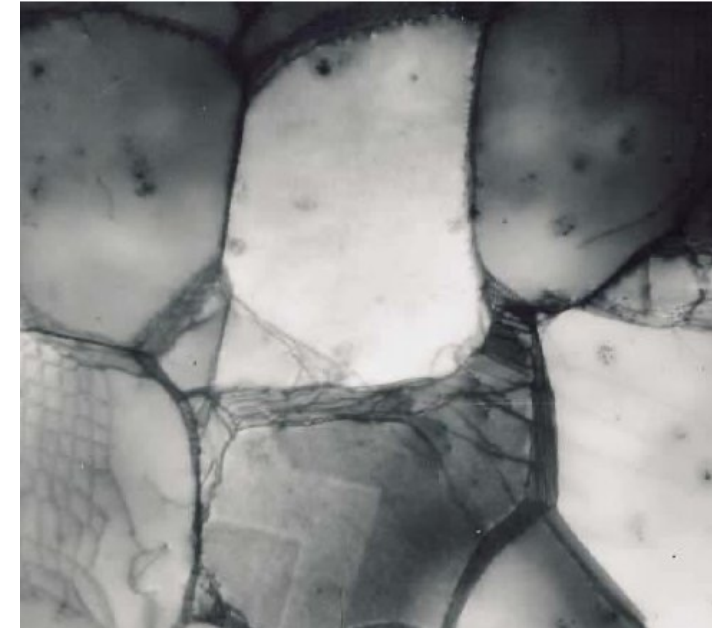
Key properties of dislocations

- ❖ The Burgers vector, $\mathbf{b}$, remains constant along the dislocation line.
- ❖ The direction of dislocation line, ξ , can change along the dislocation line.
 $\Rightarrow$ The dislocation character $(\widehat{\mathbf{b}, \xi})$ can also.
- ❖ A dislocation cannot start and end inside a perfect crystal.
 $\Rightarrow$ Dislocations form loops.
- ❖ However, a dislocation can terminate at a grain boundary, a surface, or another dislocation.
- ❖ The plane defined by $(\mathbf{b}, \xi)$ is the glide plane.
 $\Rightarrow$ No glide plane is defined for screw dislocations.
- ❖ The symbol of an edge dislocation: $\perp, \vdash, \dashv$.
- ❖ No standard symbol for screw or mixed dislocations.
- ❖ The sum of the Burgers vectors of the dislocations meeting at a node is zero.
 $\Rightarrow \sum_i \mathbf{b}_i = 0.$

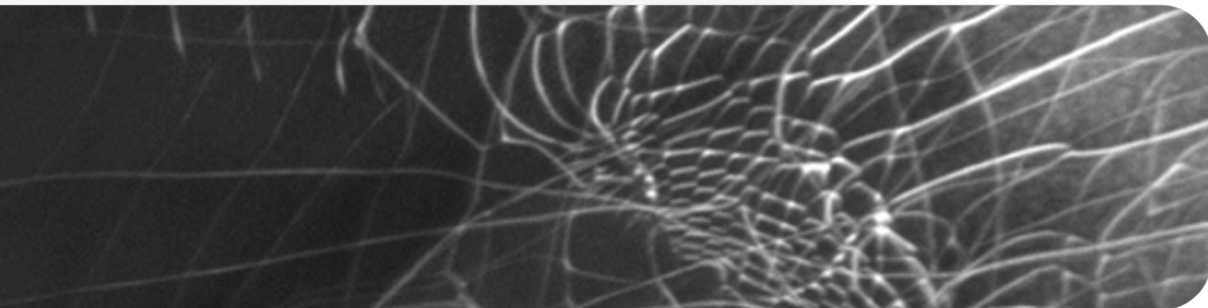


First observation of dislocations

- ❖ First direct TEM observation of dislocations in aluminum foils
- ❖ Specimens: high-purity Al, deformed and annealed, thinned to $\sim 0.5 \mu\text{m}$
- ❖ Dislocation substructures: subgrains ($\sim 1 \mu\text{m}$), low-angle boundaries, networks, nodes
- ❖ Contrast mechanism due to strain fields & Bragg diffraction, no decoration needed



➡ Preliminary but foundational: validated dislocation theory with direct imaging

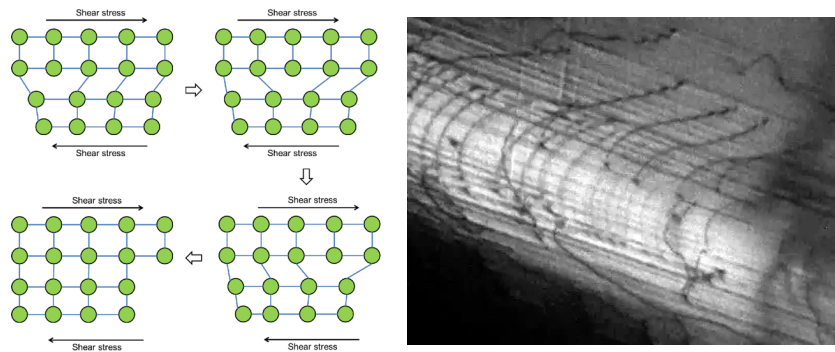


Dislocation mechanics, sources and microstructure

Dislocation movement

❖ Glide

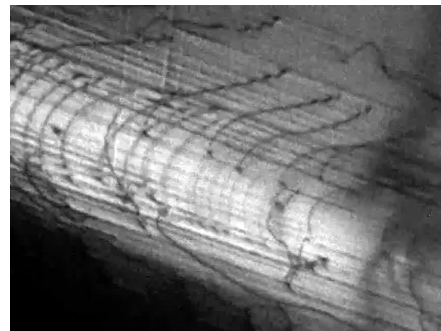
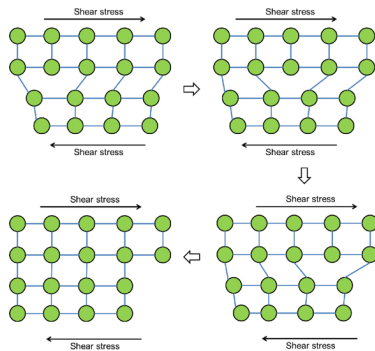
- Glide
- Motion of a dislocation within its slip plane.
- Driven by the resolved shear stress (Schmid law).
- Conserves the number of atoms → no diffusion needed.
- Main mechanism of plastic deformation at low and moderate temperatures.
- Dislocations can move at speeds approaching a significant fraction of the speed of sound in the crystal under high stress



Dislocation movement

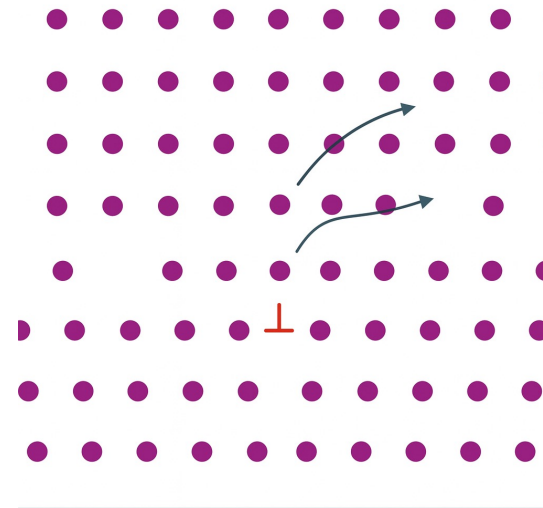
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❖ Climb

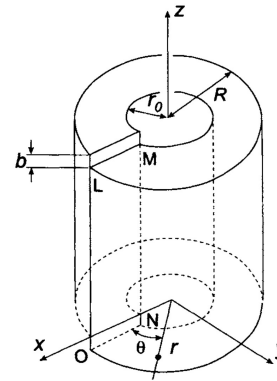
- Motion out of the slip plane.
- Controlled by diffusion of vacancies/atoms.
- Requires point defect exchange.
- Lets dislocations bypass obstacles.
- Important at high temperatures (diffusion-driven).
- Much slower than glide.



Fields around a screw dislocation line

We consider a cylindrical tube with axis Oz , containing an infinite screw dislocation line along the Oz axis, by making a cut in the xOz plane.

- ❖ The left edge of the cut is shifted by b along the $+z$ axis



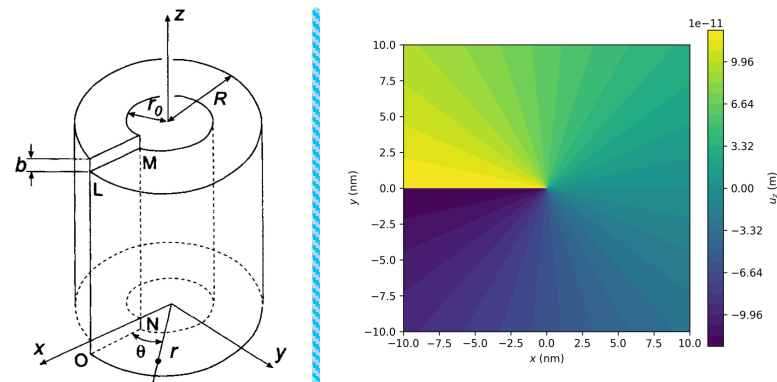
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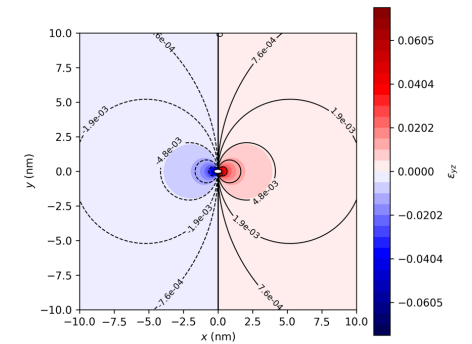
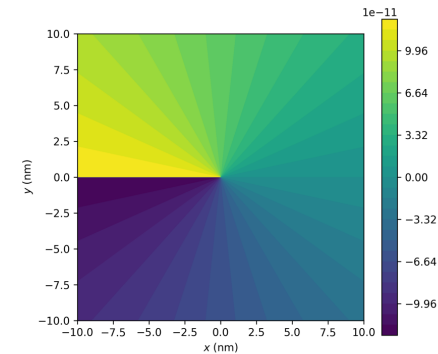
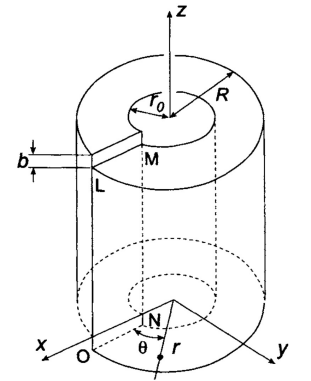
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$$\varepsilon_{ij} = \frac{1}{2} \left(\frac{\partial u_i}{\partial x_j} + \frac{\partial u_j}{\partial x_i} \right)$$

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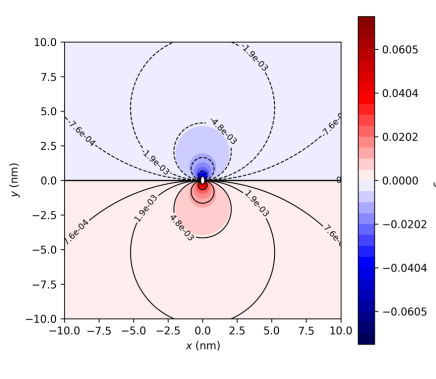
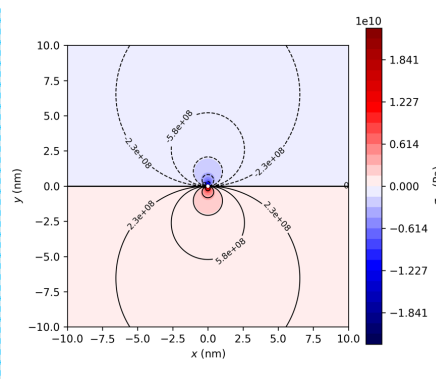
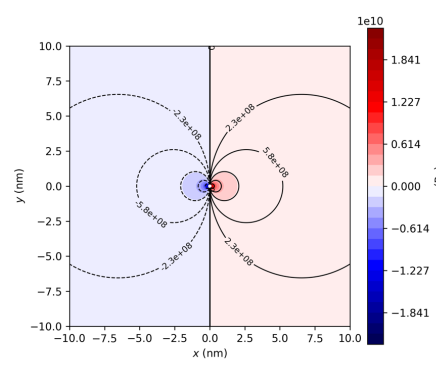
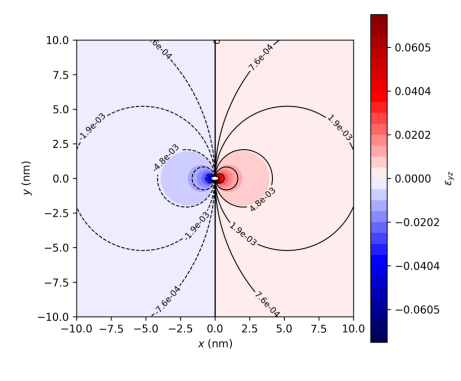
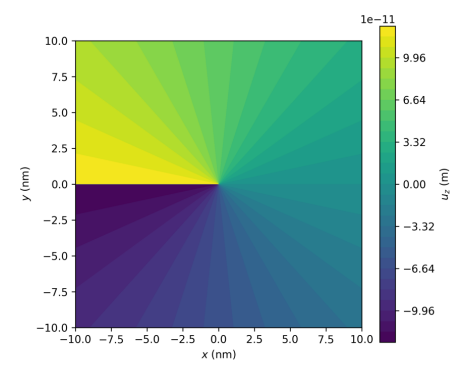
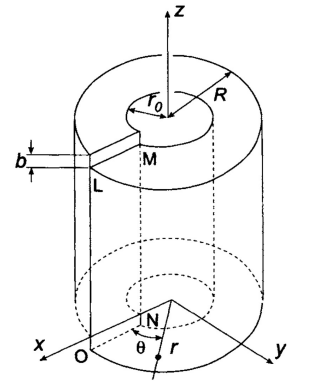
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$$\sigma_{ij} = \lambda \delta_{ij} \text{tr}(\varepsilon) + 2\mu \varepsilon_{ij}$$

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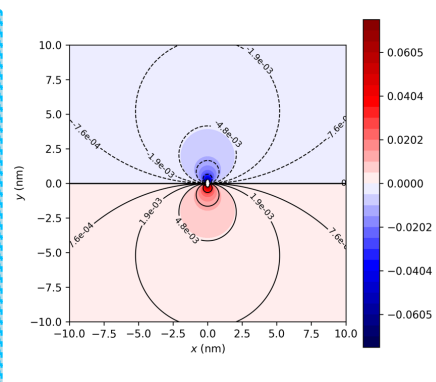
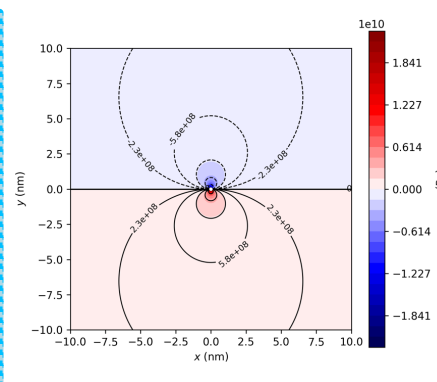
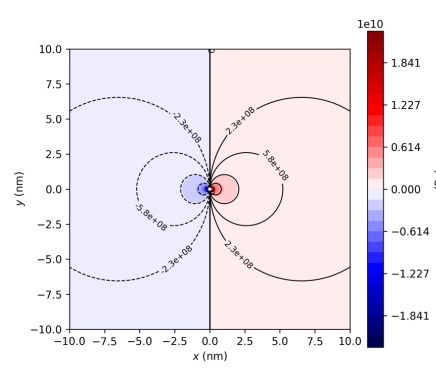
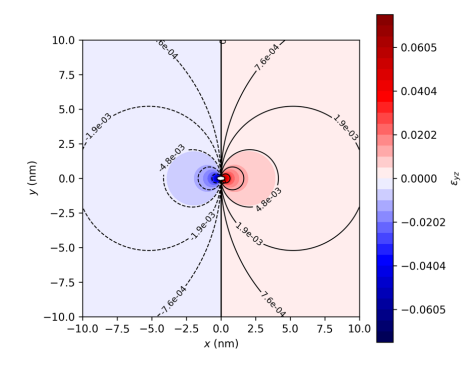
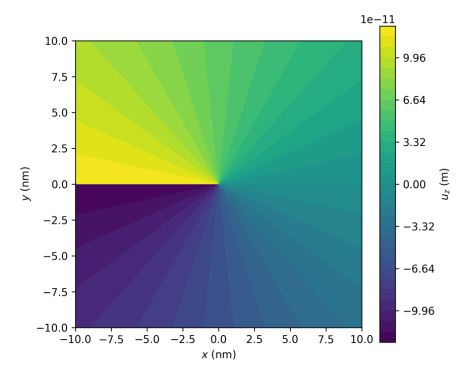
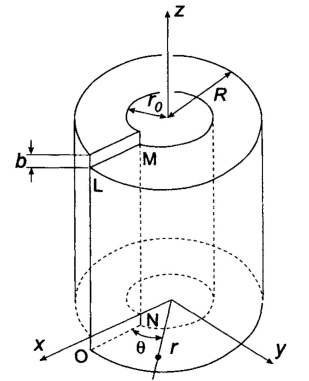
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↪ Divergence at $r = 0 \Leftrightarrow$ Core singularity problem.

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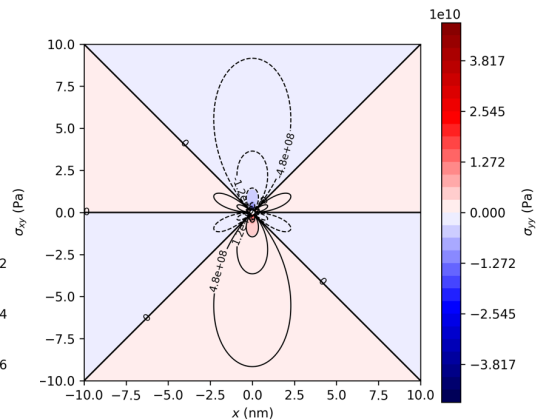
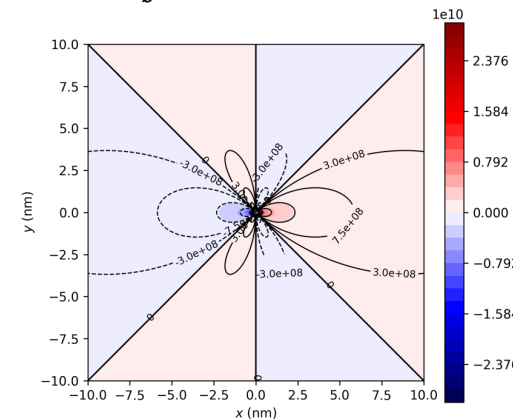
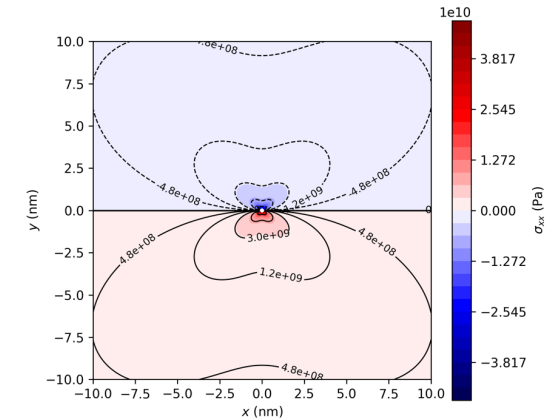
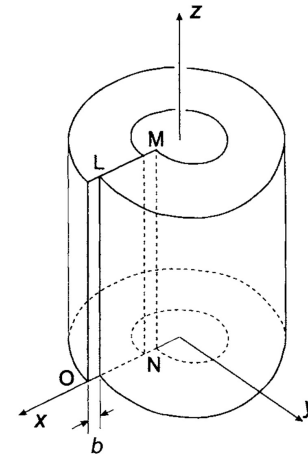
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$$\begin{aligned} \sigma_{xz} = \sigma_{zx} = \sigma_{yz} = \sigma_{zy} = \sigma_{zz} &= 0 \\ D &= \frac{Gb}{2\pi(1-\nu)} \\ \sigma_{xx} &= -Dy \frac{(3x^2+y^2)}{(x^2+y^2)^2}; \sigma_{yy} = Dy \frac{(x^2-y^2)}{(x^2+y^2)^2} \\ \sigma_{xy} = \sigma_{yx} &= -Dx \frac{(x^2-y^2)}{(x^2+y^2)^2} \\ \sigma_{zz} &= \nu(\sigma_{xx} + \sigma_{yy}) \end{aligned}$$



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- ❖ Distortions around dislocations mean the crystal is not in its lowest energy state. The excess energy is stored as strain energy.

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$$w = \frac{1}{2} \varepsilon_{ij} \sigma_{ij} \Rightarrow W = \frac{1}{2} \int \varepsilon_{ij} \sigma_{ij} dV$$

❖ The total strain energy per unit length for a dislocation in a cylinder of radius R :

○ Screw

$$W_s \sim \frac{Gb^2}{4\pi} \ln \frac{R}{r_0}$$

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$$W_m \sim \frac{Gb^2[1 - \nu \cos^2(\mathbf{b}, \boldsymbol{\xi})]}{4\pi(1-\nu)} \ln \frac{R}{r_0}$$

Strain energy of a dislocation line

❖ Distortions around dislocations mean the crystal is not in its lowest energy state. The excess energy is stored as strain energy.

❖ The energy density is defined as:

$$w = \frac{1}{2} \varepsilon_{ij} \sigma_{ij} \Rightarrow W = \frac{1}{2} \int \varepsilon_{ij} \sigma_{ij} dV$$

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↪ Dislocation energy $\propto Gb^2 \ln \frac{R}{r_0} \rightarrow$ diverges in infinite crystal, cut off by the core.

Forces on dislocations

Glide force

- ❖ Driving force for dislocation motion in the slip plane.
- ❖ Origin: resolved shear stress acting on the Burgers vector.
- ❖ The glide force per unit length:
$$f_{\text{glide}} = \tau_{RSS} b$$
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- ❖ Fundamental expression of the force exerted by a stress field on a dislocation.

$$\mathbf{F}_{PK} = (\boldsymbol{\sigma} \cdot \mathbf{b}) \times \boldsymbol{\xi}$$

- ❖ Glide is the resolved component in the slip plane ($\mathbf{n}$), climb corresponds to the normal component.

- Glide:

$$f_{glide} = (\mathbf{F}_{PK} \cdot \mathbf{s}) \times s$$

$(s = n \times \xi)$

⇒ **Drives dislocation motion by glide.**

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- ❖ A dislocation line behaves like a stretched string with an energy per unit length:

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- ❖ Restoring force per unit length:

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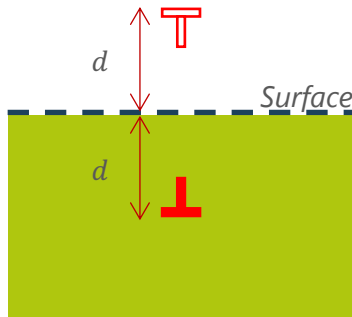
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↪ Dislocation motion results from the balance between external driving forces and internal restoring forces.

Effect of free surfaces on dislocations

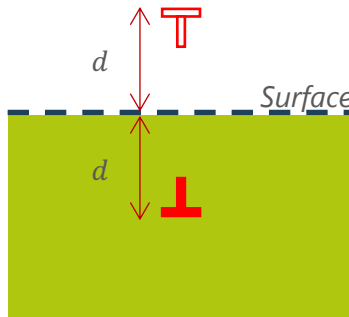


❖ Surface presence alters the elastic field of a dislocation loop.

⇒ An image force appears to satisfy the zero-traction boundary condition at the surface.

⇒ Physically, it corresponds to the attraction between the real dislocation and a virtual dislocation of opposite Burgers vector ($-b$) placed symmetrically on the other side of the surface.

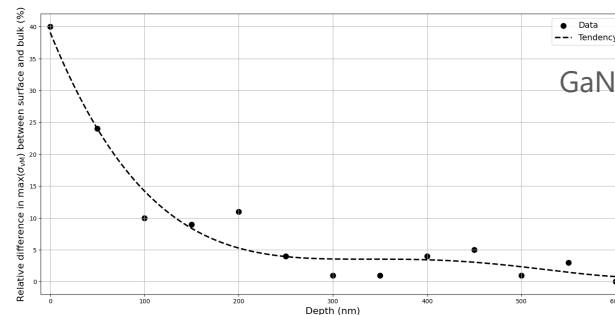
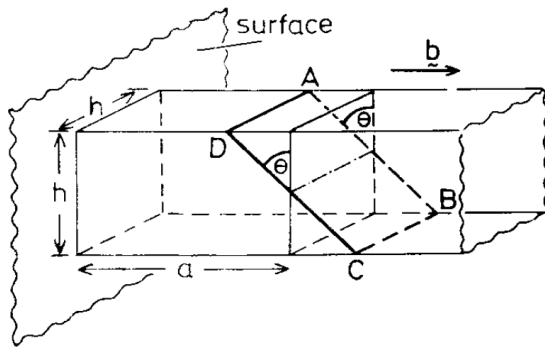
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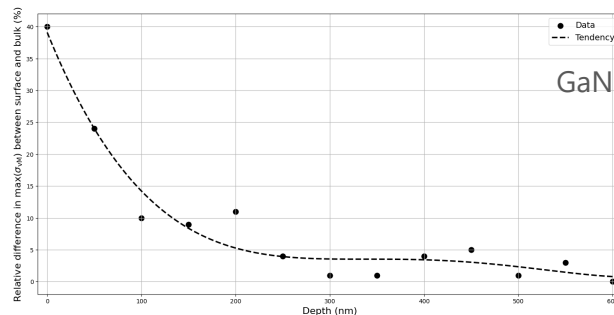
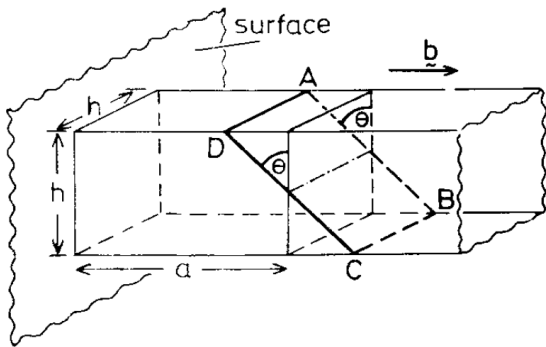
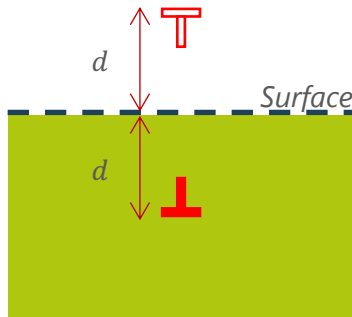
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❖ Surface effects are short-ranged:

- Significant influence when depth $a \leq 2h - 3h$
 a : distance from loop center to surface; h : loop size (length of one side of rectangular loop)
- For $a > 3h$, the dislocation behaves as in an infinite medium.

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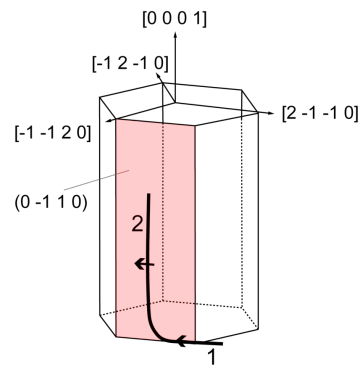
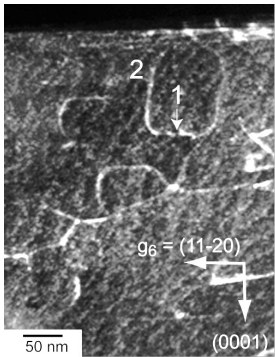
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➡ The behavior of dislocations is influenced by the presence of free surfaces

Some dislocation configurations

Cross-slip

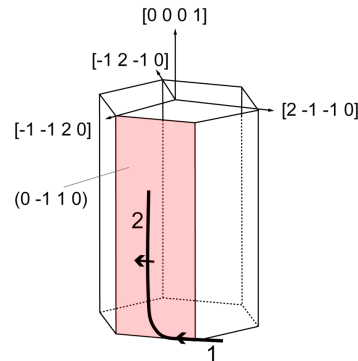
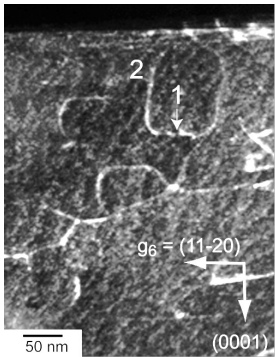
- ❖ Mechanism: a screw dislocation can move from its original slip plane to a cross-slip plane.
- ❖ **Effect:** essential for work hardening



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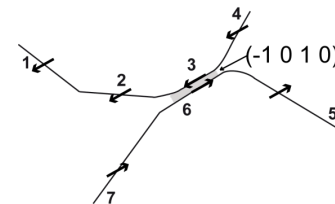
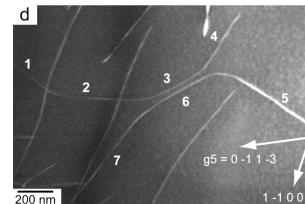
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Dipole/pair

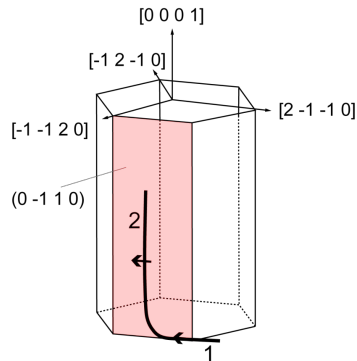
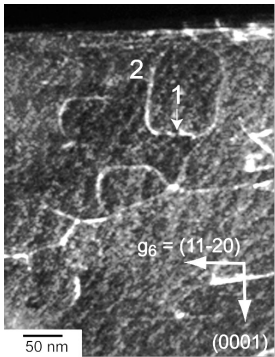
- ❖ Two dislocations on parallel slip planes.
 - Opposite signs → form a dipole
 - At small separation, they attract and create a stable locked pair.
 - Effect: dipoles act as strong obstacles to further glide
 - ⇒ **Contribute to strain hardening.**
 - Same sign → form a pair.
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 - Effect: can act as mobile sources of stress fields and enhance forest interactions.



Some dislocation configurations

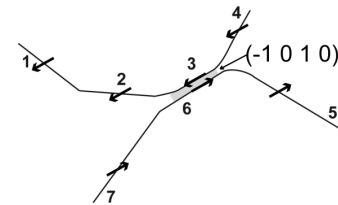
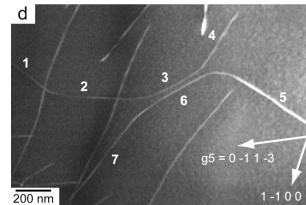
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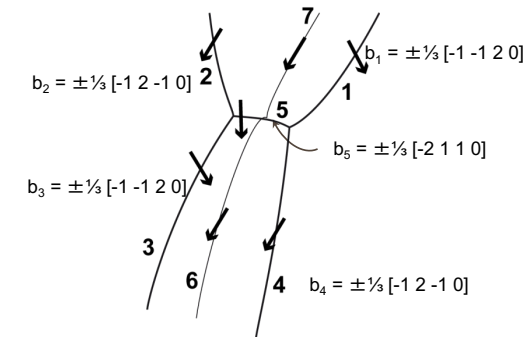
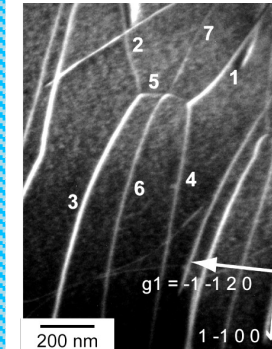
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Reaction

- ❖ When two dislocations on different slip systems interact, they can react:

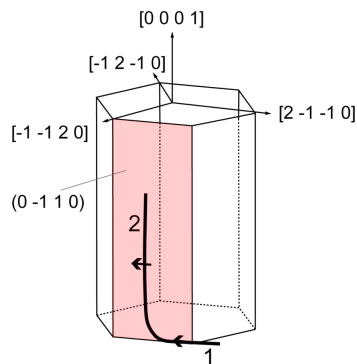
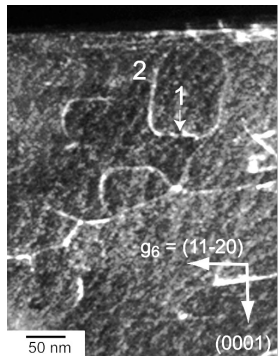
$$\mathbf{b}_1 + \mathbf{b}_2 \rightarrow \mathbf{b}_3$$
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⇒ Strong barriers to motion
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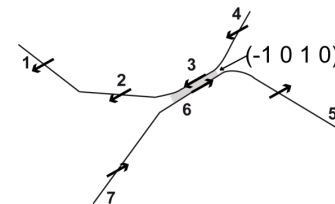
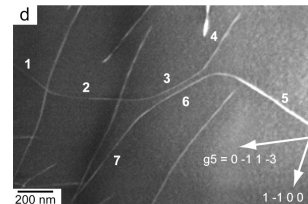
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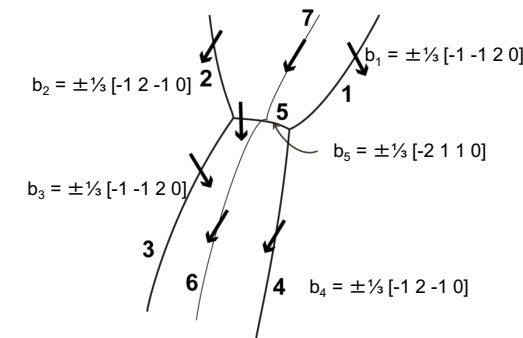
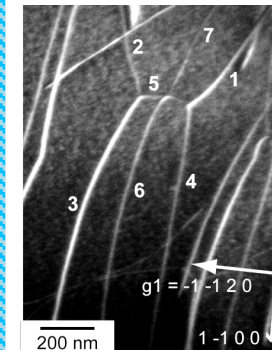
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Dislocation configurations are key to understanding how dislocation interactions lead to strain/work hardening.

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99

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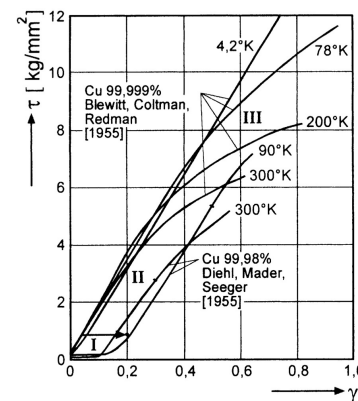
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- ✓ Stage III onset shifts to lower strains as T increases.

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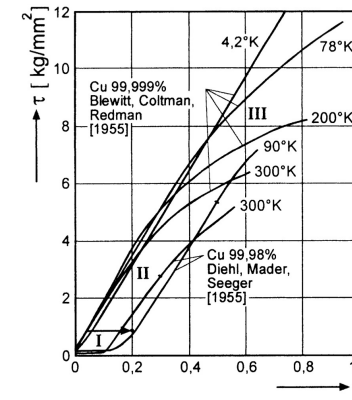
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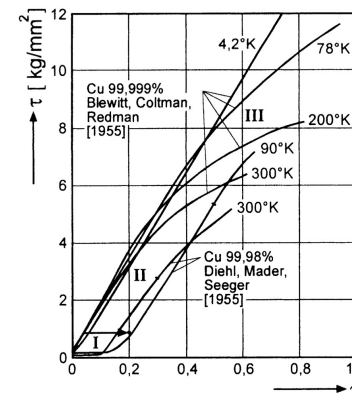


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❖ Consequence on hardening rate $\theta = d\tau/d\gamma$:

$$\theta = \theta_0 - \theta_{recovery}(T, \dot{\gamma})$$

$\Rightarrow \theta$ decreases with increasing temperature and decreasing strain rate.

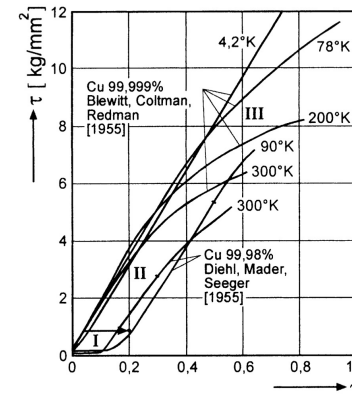


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- ✓ Schematic $\tau\theta - \tau$ plot.
 - ✓ Storage dominates at low stress.
 - ✓ Dynamic recovery increases with τ .
- $\Rightarrow$ **Dynamic recovery accelerates hardening rate θ decreases until plastic flow saturates.**

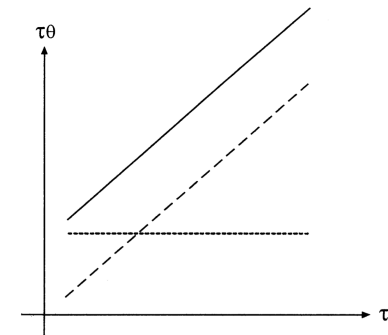


Fig. 14. Dislocation storage rate when the mean free path is constant (dots); when it is proportional to the dislocation spacing (dashes); and when both superpose (solid).

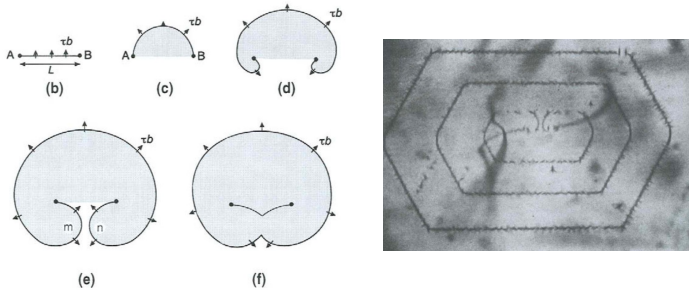
Work hardening is the macroscopic signature of dislocation storage controlled by the configurations generated during plastic flow.

Dislocation sources

Frank-Read

- ❖ Pinned dislocation segment bows out under shear stress.
- ❖ At $\sim 180^\circ$ curvature, reconnection occurs
 $\Rightarrow$ dislocation loop emitted.
- ❖ The process repeats $\rightarrow$ dislocation multiplication.
- ❖ Critical activation stress:

$$\tau_{max} = \frac{\alpha Gb}{L}; \alpha = 0.5 - 1$$

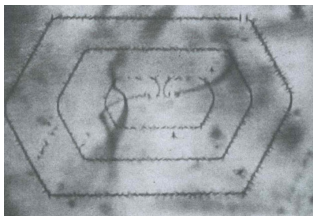
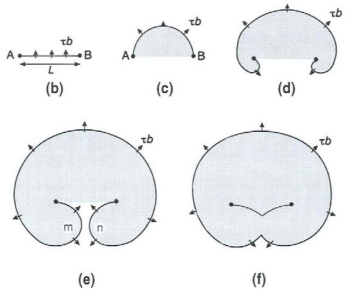


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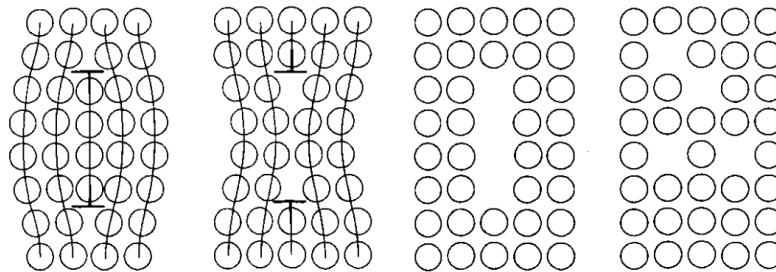
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Vacancy collapse

- ❖ Cluster of vacancies coalesces into a void-like defect.
- ❖ Collapse produces a prismatic dislocation loop.
- ❖ Important in irradiated and quenched materials.

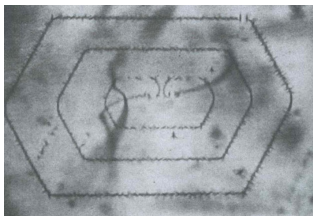
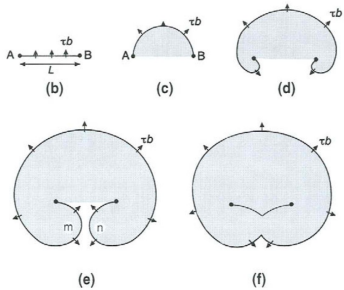


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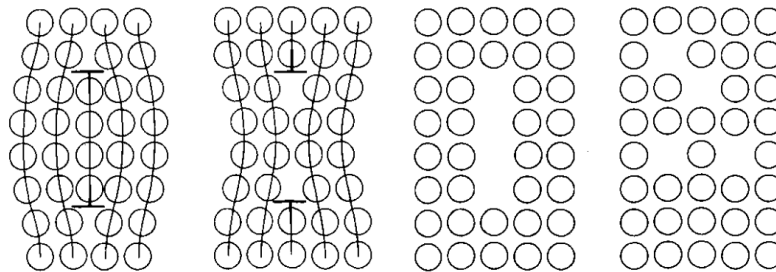
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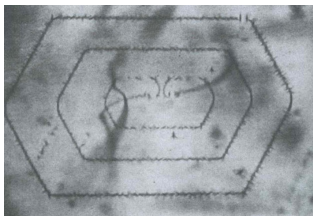
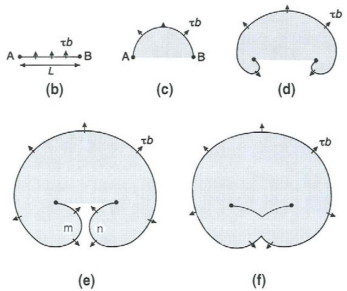
- ❖ Single-arm sources (pinned at one end).
- ❖ Cross-slip of screw dislocations.
- ❖ Dislocation reactions/junctions.
- ❖ Surface/interface sources.

Dislocation sources

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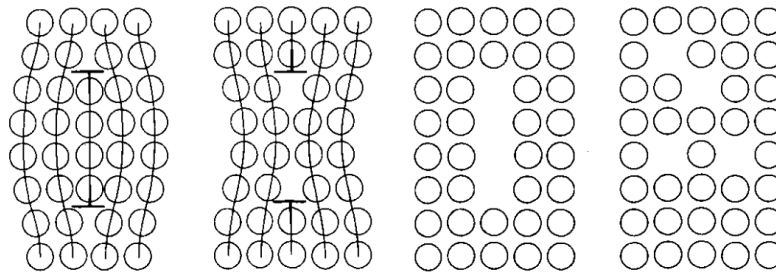
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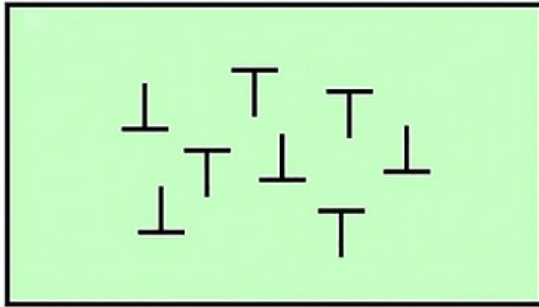
Other

- ❖ Single-arm sources (pinned at one end).
- ❖ Cross-slip of screw dislocations.
- ❖ Dislocation reactions/junctions.
- ❖ Surface/interface sources.

Dislocation sources sustain the dislocation population required for plastic deformation..

Different types of dislocation densities

Statistically stored dislocations (SSD)

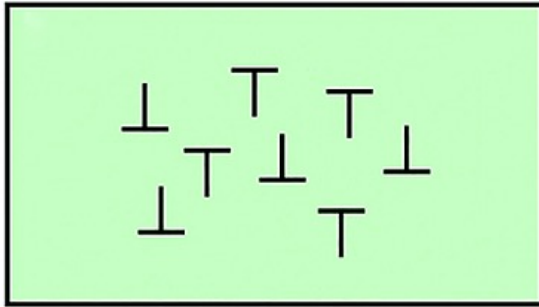


⇒ No lattice curvature at long range

Different types of dislocation densities

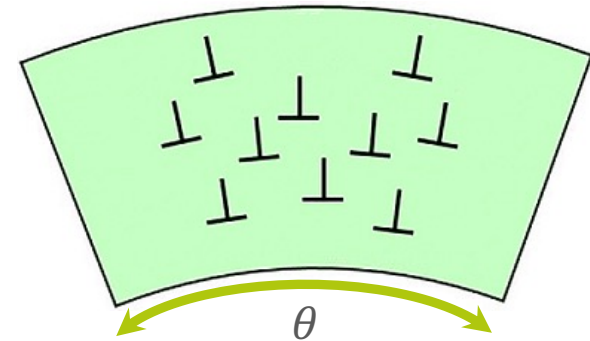
110

Statistically stored dislocations (SSD)



⇒ No lattice curvature at long range

Geometrically necessary dislocations (GND)



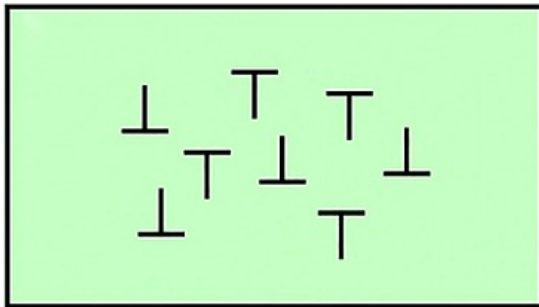
⇒ Lattice curvature at long range

$$\rho_{GND} \propto \frac{\theta}{\|b\| \delta x}$$

Different types of dislocation densities

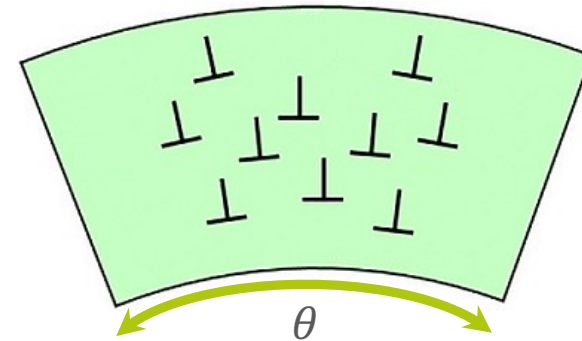
111

Statistically stored dislocations (SSD)



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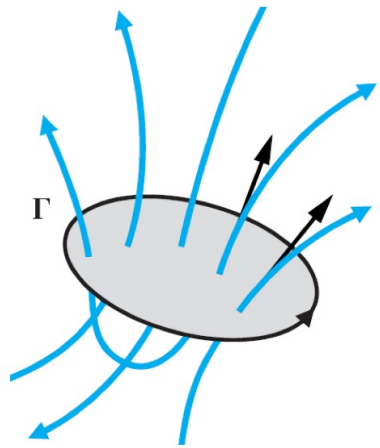
⇒ Lattice curvature at long range

$$\rho_{\text{GND}} \approx \frac{1}{\|\mathbf{b}\|} \|\boldsymbol{\alpha}\|; \|\boldsymbol{\alpha}\| = \sqrt{\alpha_{ij} \cdot \alpha_{ij}}$$

$$\boldsymbol{\alpha} = \text{curl } \boldsymbol{\varepsilon} + \text{tr}(\boldsymbol{\kappa}_e) \cdot \mathbb{I} - \boldsymbol{\kappa}_e^T$$

$$\kappa_{ij} \cong \frac{\Delta \omega_i}{\Delta x_j}; \varepsilon_{ij} = \frac{1}{2} \left(\frac{\partial u_i}{\partial x_j} + \frac{\partial u_j}{\partial x_i} \right)$$

The Nye tensor



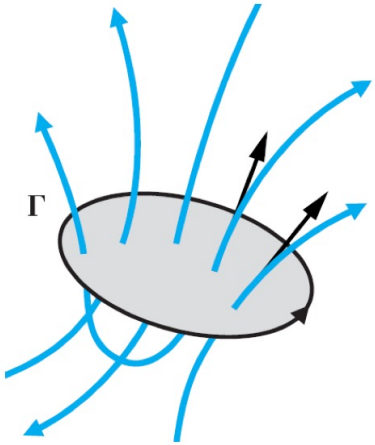
The Nye tensor

- The net Burgers vector on the closed circuit Γ limiting the surface S

$$\mathbf{B} = \left(\oint_{\Gamma} \mathbf{u}(\mathbf{x}) \mathbf{n} dS \right) \mathbf{b} = \oint_{\Gamma} \tilde{\boldsymbol{\alpha}} \mathbf{n} dS$$

Where

$$\tilde{\boldsymbol{\alpha}} = \mathbf{b} \otimes \mathbf{u}(\mathbf{x})$$



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Edge dislocations (1 of 2 types)

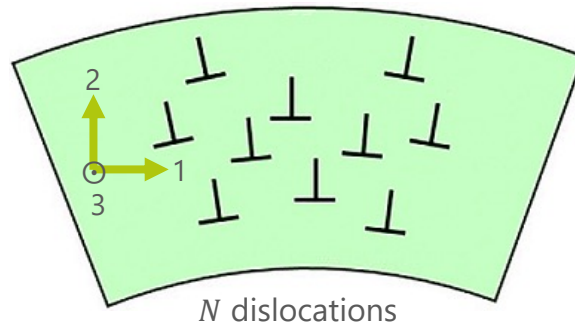
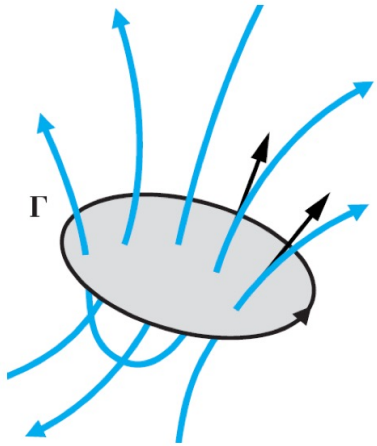
$$\mathbf{B}_{edge} = N \mathbf{b} \mathbf{e}_1 = \tilde{\boldsymbol{\alpha}} \mathbf{e}_3 S$$

$$\tilde{\boldsymbol{\alpha}} = \frac{N}{S} \mathbf{b} \otimes \mathbf{u}(\mathbf{x}) = \frac{N}{S} b \mathbf{e}_1 \otimes \mathbf{e}_3 = \rho_{GND} \mathbf{e}_1 \otimes \mathbf{e}_3$$

Screw dislocations

$$\mathbf{B}_{screw} = N \mathbf{b} \mathbf{e}_3 = \tilde{\boldsymbol{\alpha}} \mathbf{e}_3 S$$

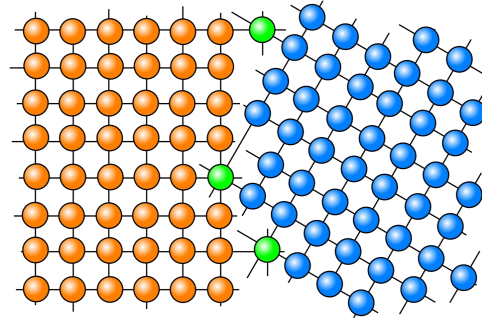
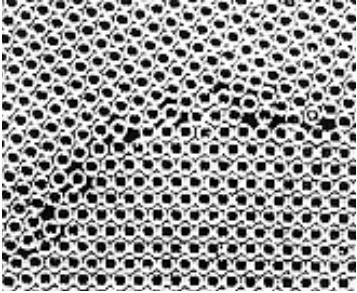
$$\tilde{\boldsymbol{\alpha}} = \frac{N}{S} \mathbf{b} \otimes \mathbf{u}(\mathbf{x}) = \frac{N}{S} b \mathbf{e}_3 \otimes \mathbf{e}_3 = \rho_{GND} \mathbf{e}_3 \otimes \mathbf{e}_3$$



N dislocations

Grain boundaries

L. Bragg & J.F. Nye, *Proc. R. Soc. Lond.* (1947)

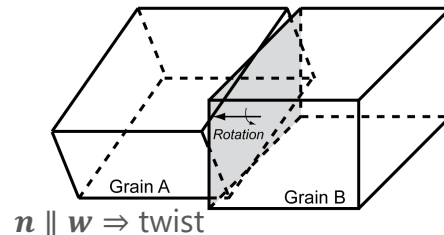
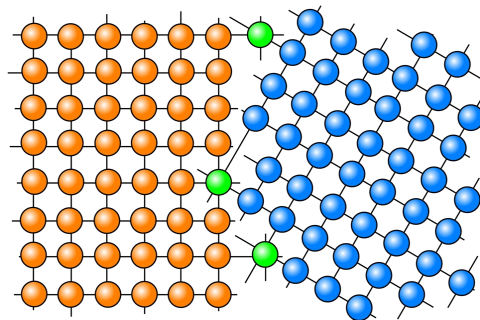
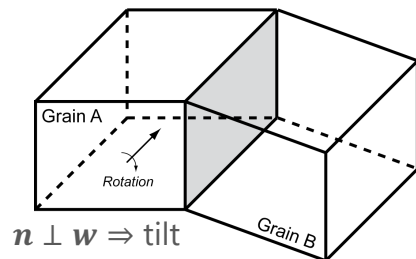
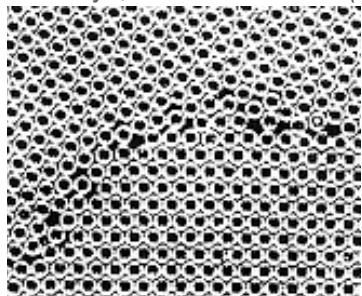


❖ Definition:

- GBs are interfaces where crystals of different orientations meet in a polycrystalline material.
- Five parameters to describe a GB
 - ✓ 1 disorientation angle (θ) $\rightarrow$ 1 parameter
 - ✓ Unitary rotation vector ($\mathbf{w}$) $\rightarrow$ 2 parameters
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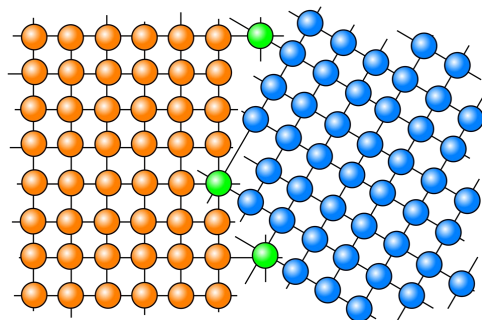
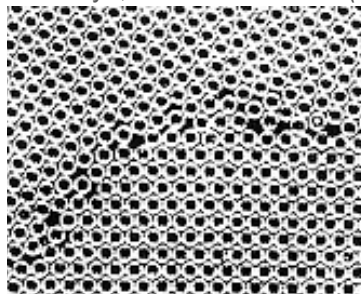
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- *Tilt GB*: $\mathbf{n} \perp \mathbf{w}$
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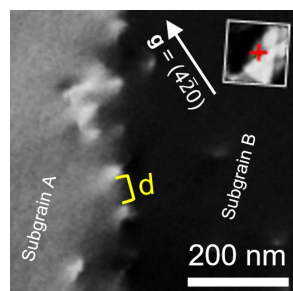
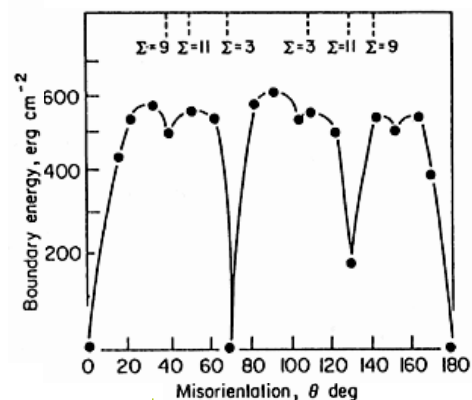
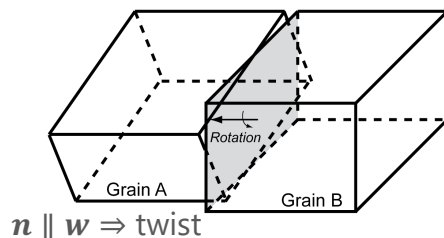
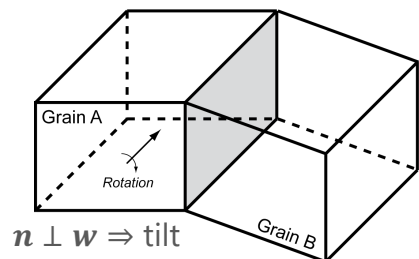
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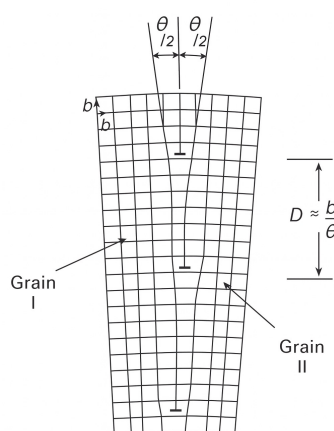
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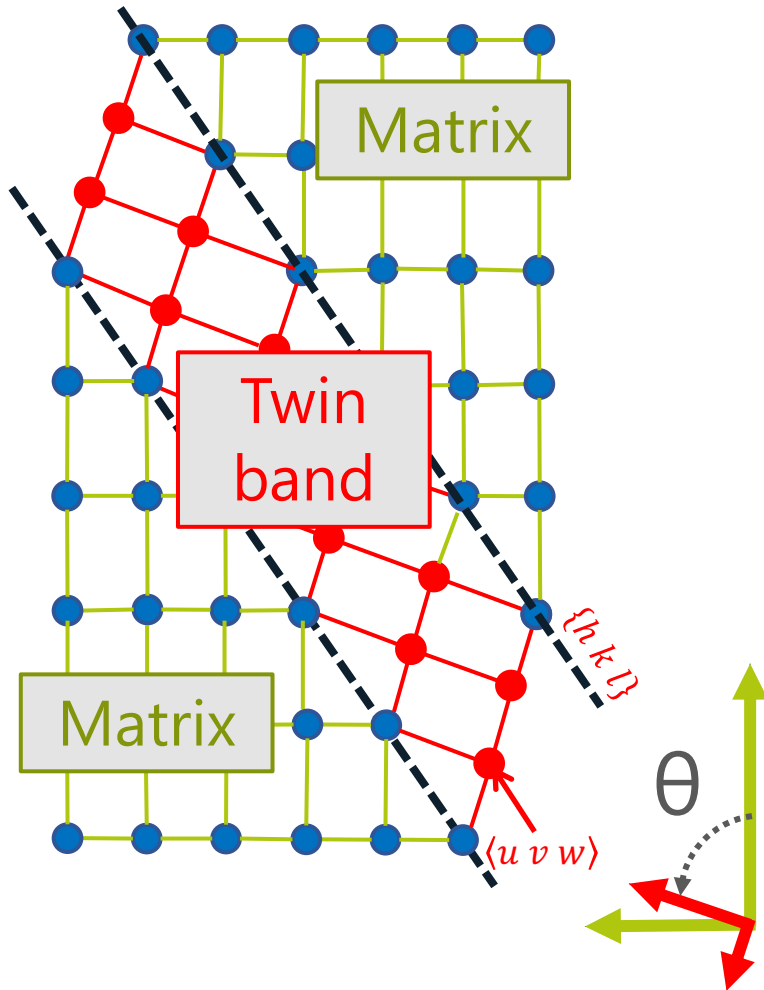
$$\theta = 2 \sin^{-1} \left(\frac{|\mathbf{b}|}{2D} \right)$$
- High-Angle GB (HAGB): $\theta \geq 15^\circ$



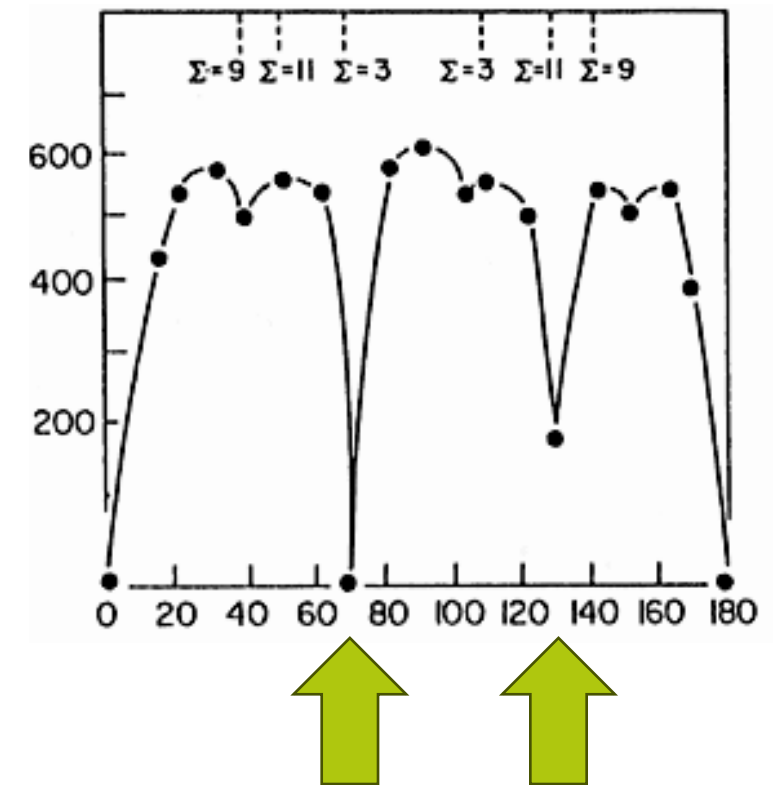
- $D = 60 \pm 5.52$ nm
- $\mathbf{b} = \frac{a}{2} \langle 110 \rangle$
- $\Rightarrow \theta = 0.24 \pm 0.02^\circ$



Focus on the twinning



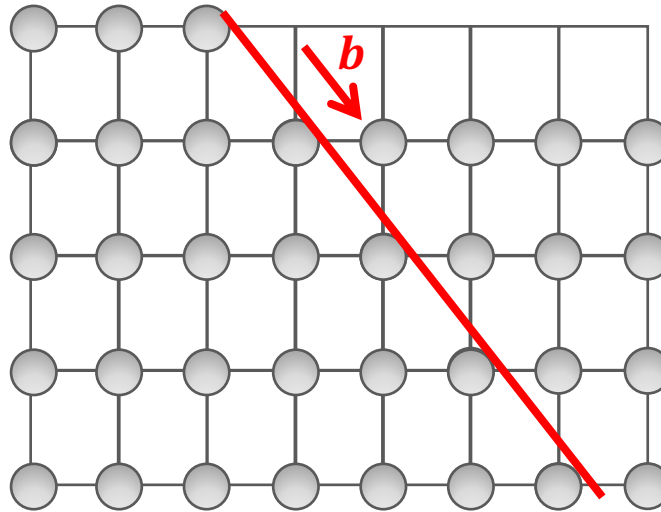
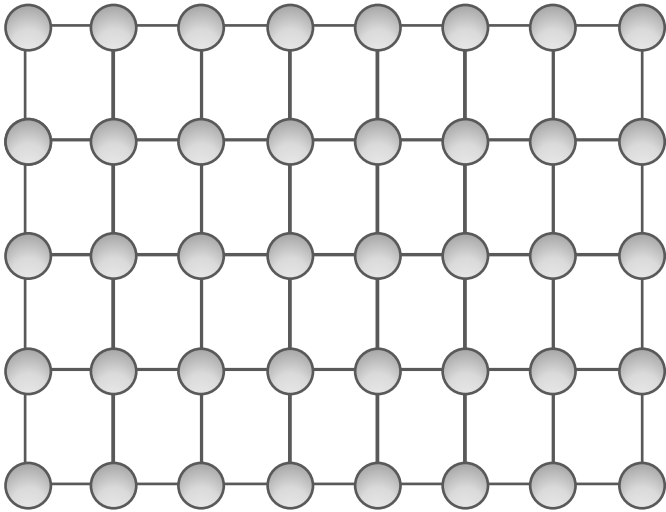
- ❖ Identical crystalline structure
- ❖ Mirror reflection
- ❖ System: $\langle u \ v \ w \rangle \{h \ k \ l\}$
- ❖ Low-energy HAGB (Σ 3 in FCC)
- ❖ Tilted by a specific angle (θ)



Partial dislocations and stacking fault

❖ If $\mathbf{b}$ is a vector of the lattice

⇒ **Perfect dislocation**



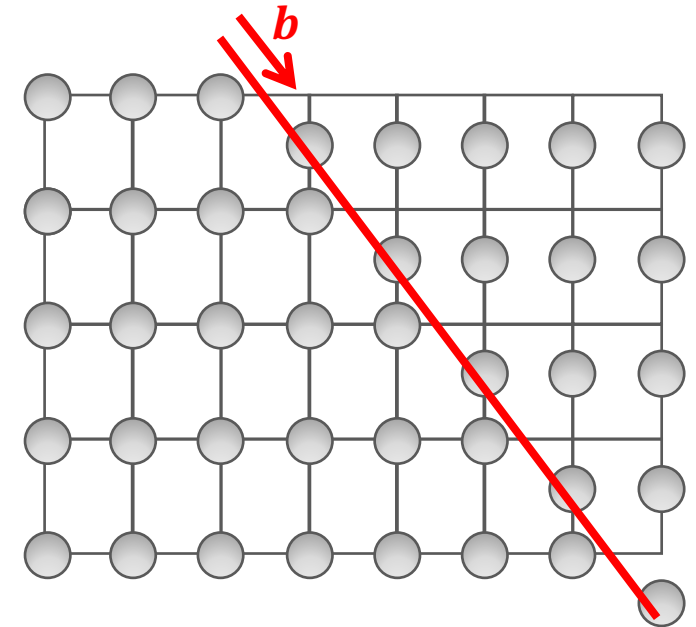
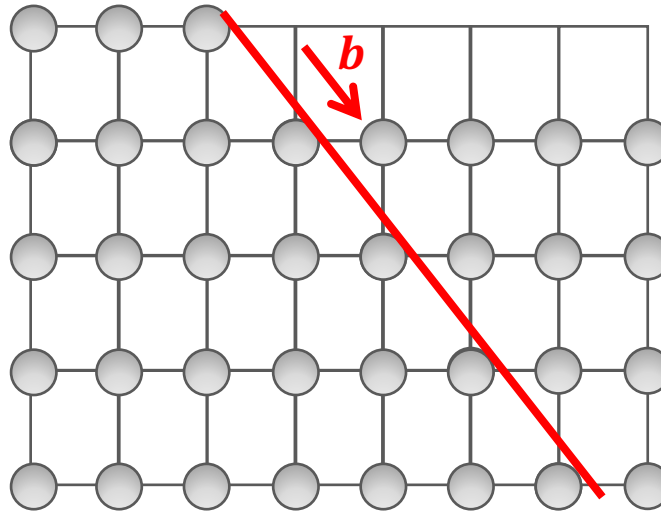
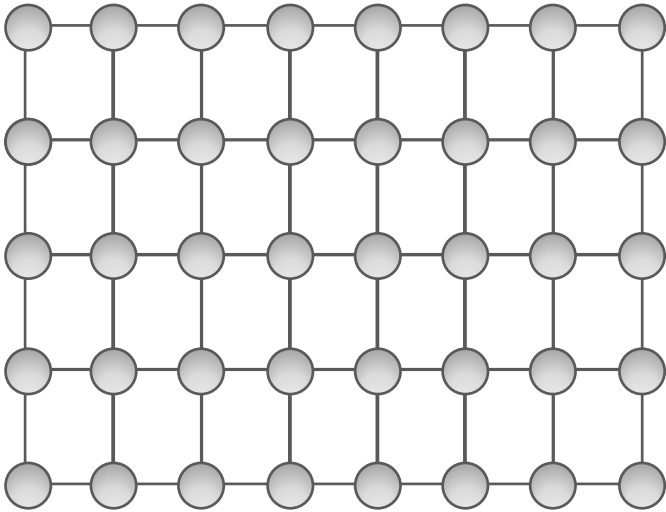
Partial dislocations and stacking fault

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❖ If $\mathbf{b}$ is smaller than a vector of the lattice

⇒ **Partial dislocation and stacking fault**



Partial dislocations and stacking fault

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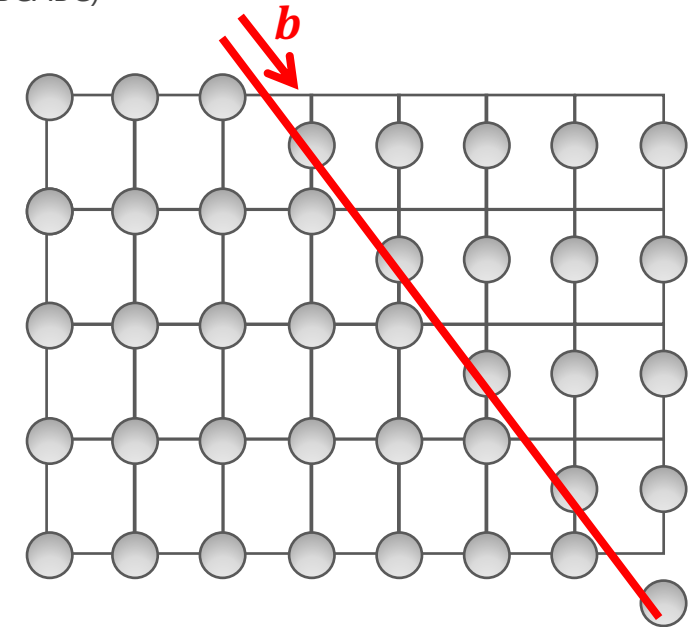
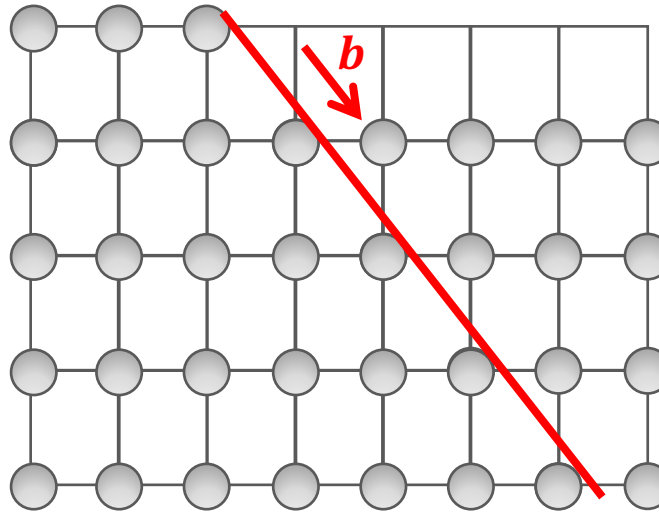
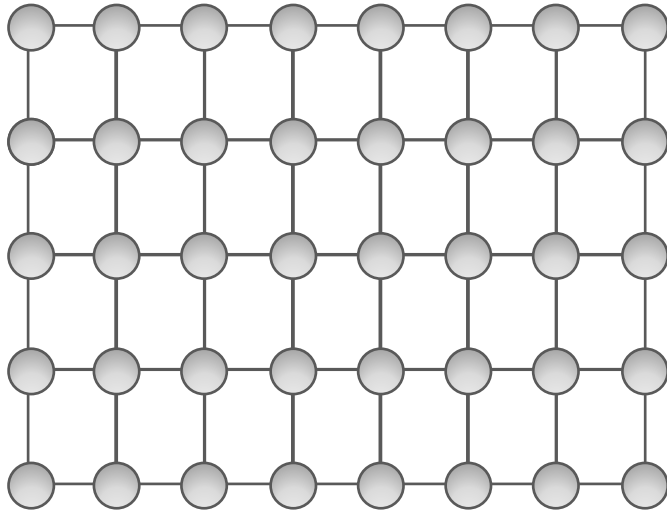
⇒ **Perfect dislocation**

❖ If b is smaller than a vector of the lattice

⇒ **Partial dislocation and stacking fault**

❖ Stacking faults

- Planar defect where the normal stacking sequence of close-packed planes is interrupted.
- Types:
 - Intrinsic stacking fault → missing plane in the sequence (ABCAB_ ABC)
 - Extrinsic stacking fault → extra plane inserted. (ABCABABCABC)



Peierls stress and γ -surface

❖ Peierls stress

- **Definition:** minimum shear stress to move a dislocation across the periodic lattice potential.
- **Origin:** the dislocation core experiences the periodic γ -surface energy

$$\tau_P \approx CG \exp \left\{ -\frac{2\pi w}{b} \right\}$$

(C : dimensionless constant; w : dislocation core width)

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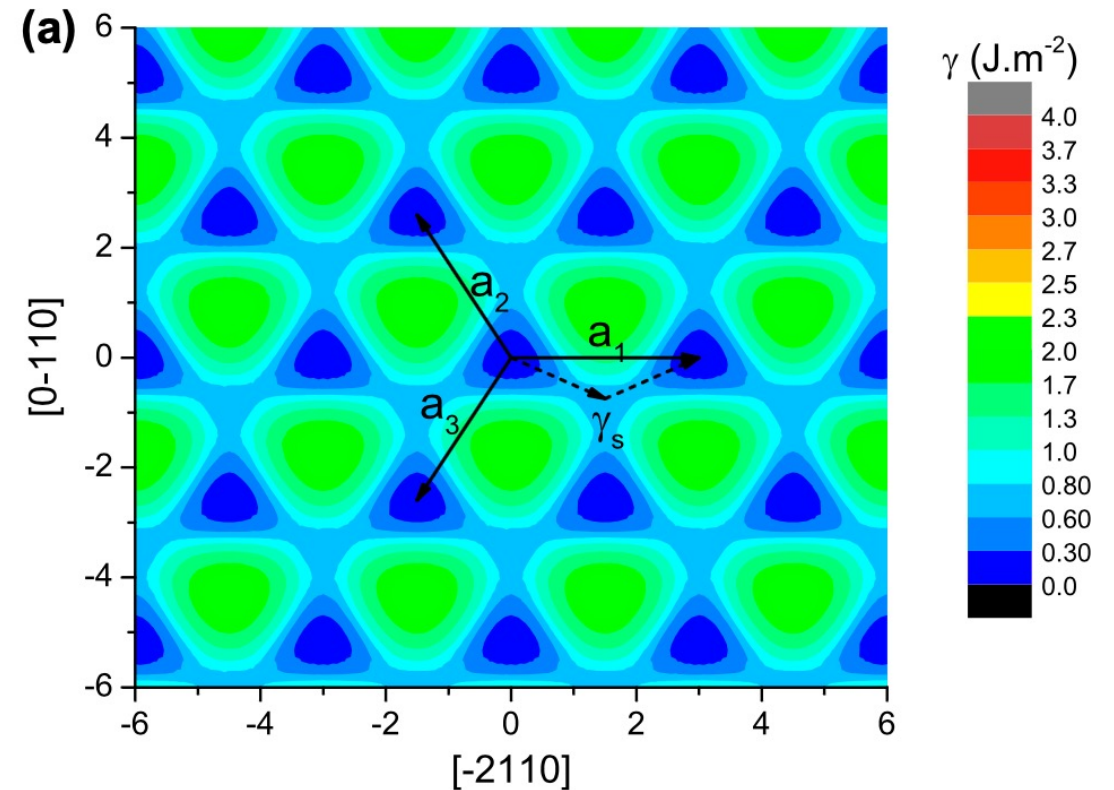
(C : dimensionless constant; w : dislocation core width)

❖ Effect on dissociation

- Perfect dislocation splits into two partials.
- $b \rightarrow p_1 + p_2 + SF$
- A stacking fault forms between the partials (SF).
- Separation distance between partials:

$$d \approx \frac{Gb^2}{8\pi\gamma(1-\nu)}$$

- Effect of the stacking fault energy (γ) on τ_P :
 - Low $\gamma \rightarrow$ large separation, very low τ_P
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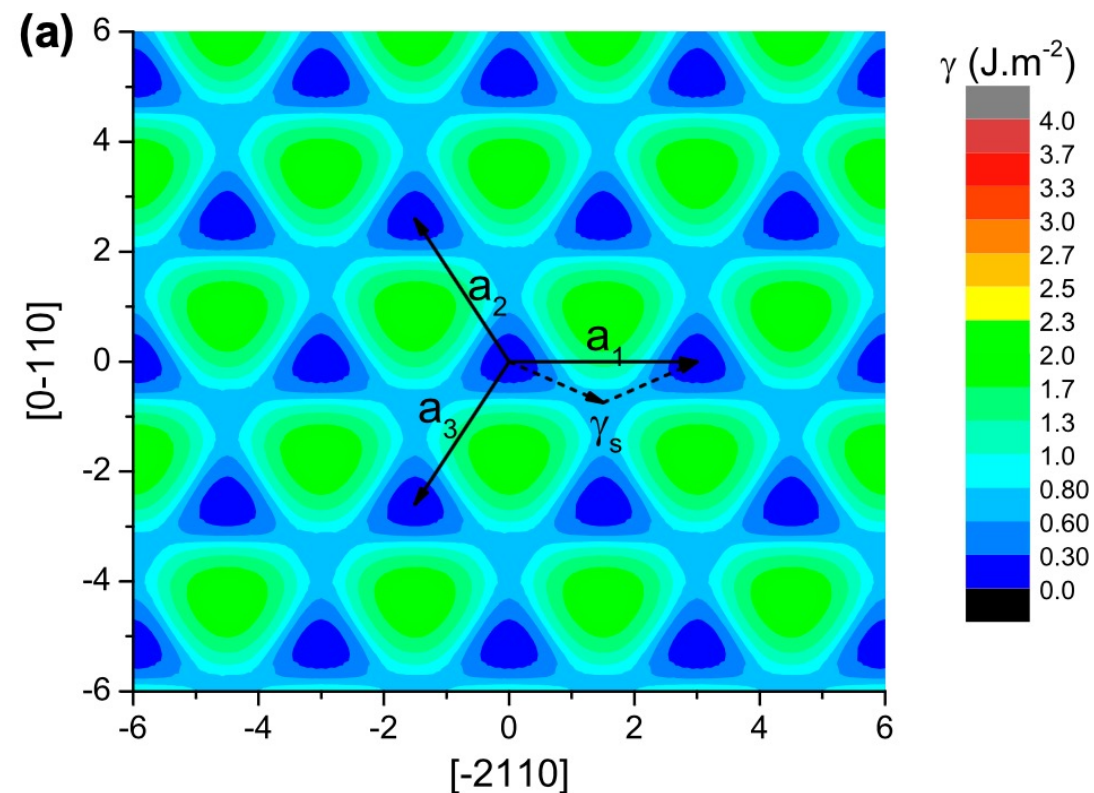
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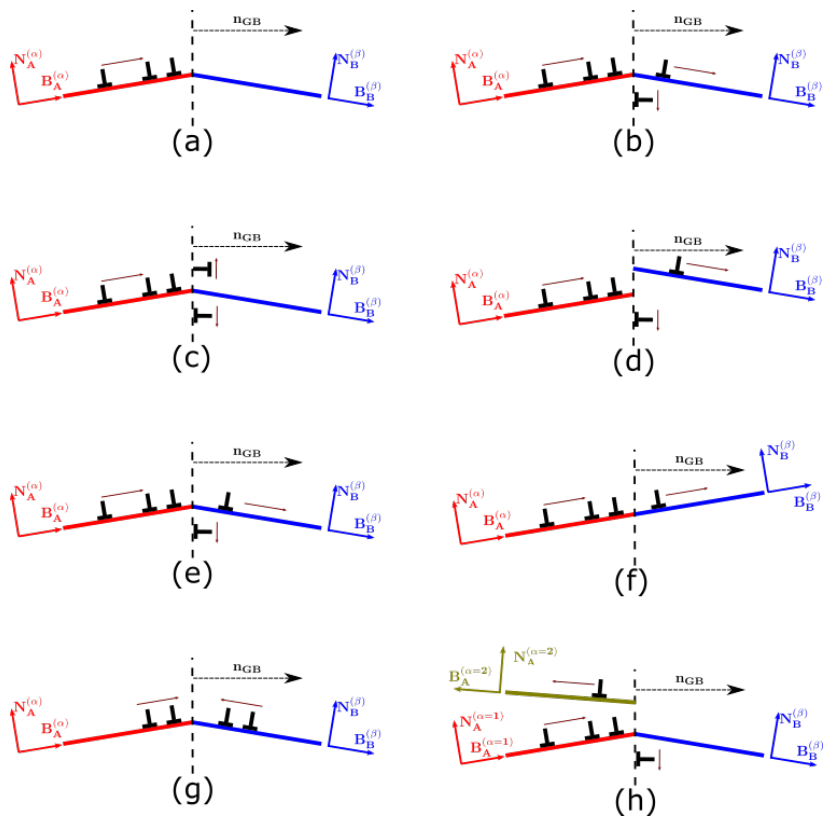


↳ Dissociation into partials lowers the Peierls stress by effectively broadening the dislocation core.

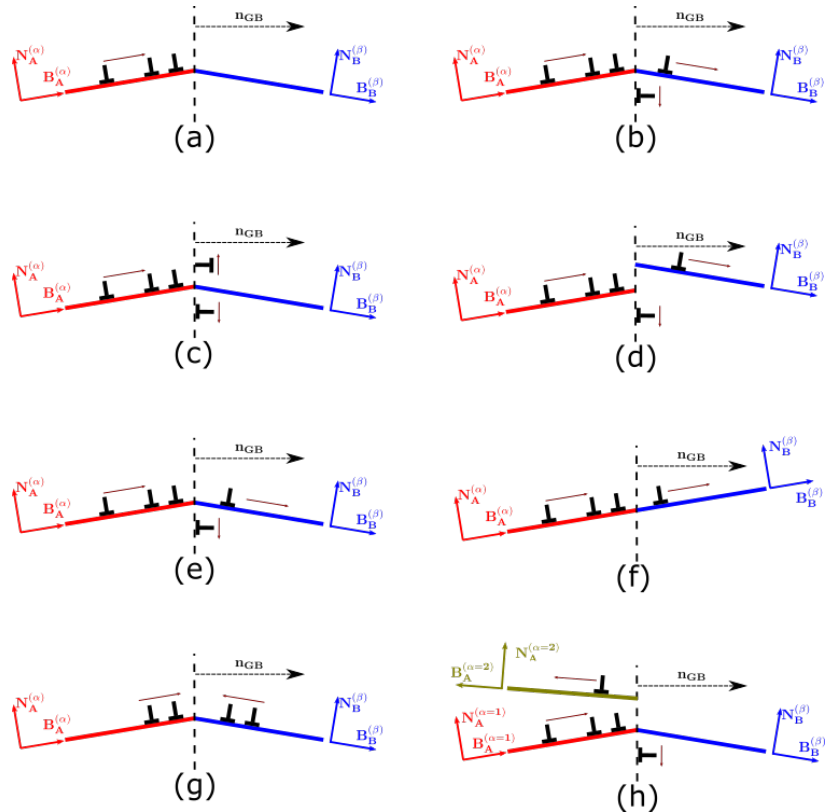
Dislocation/ grain boundary interactions

❖ Blocking (pile-up)

- Dislocations accumulate at the GB.
- Generates high local stress concentration.



Dislocation/ grain boundary interactions



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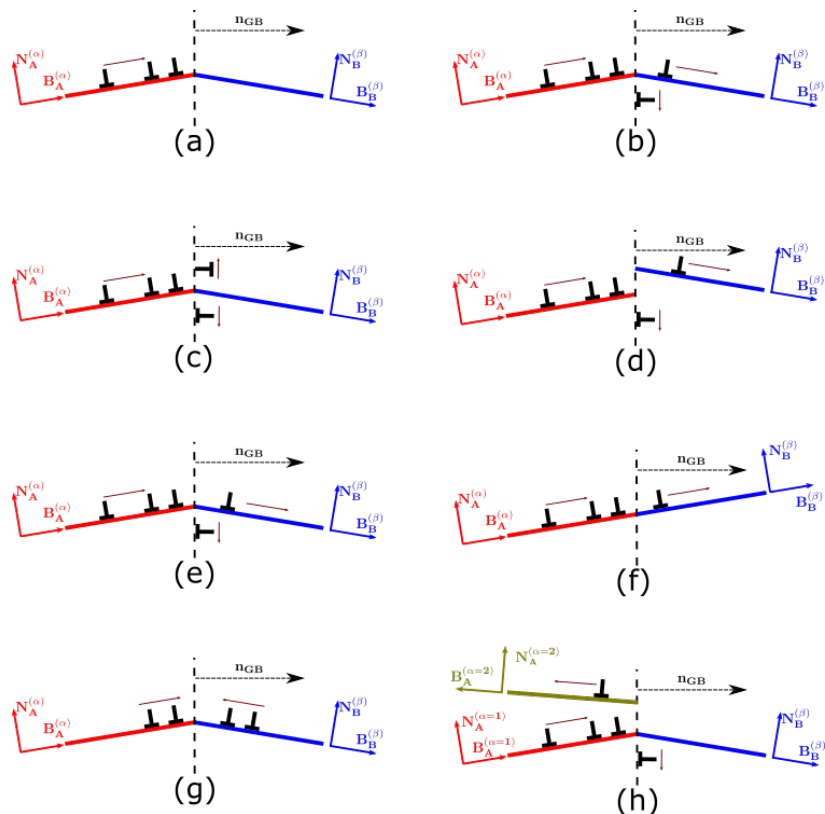
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❖ Transmission across the GB

- Dislocation passes into the adjacent grain.
- Governed by criteria:
 - Geometrical criterion:

$$LC_{\alpha\beta} = (N_{\alpha}^A \cdot N_{\beta}^B) \cdot (B_{\alpha}^A \cdot B_{\beta}^B) + (N_{\alpha}^A \cdot B_{\beta}^B) \cdot (N_{\beta}^B \cdot B_{\alpha}^A)$$

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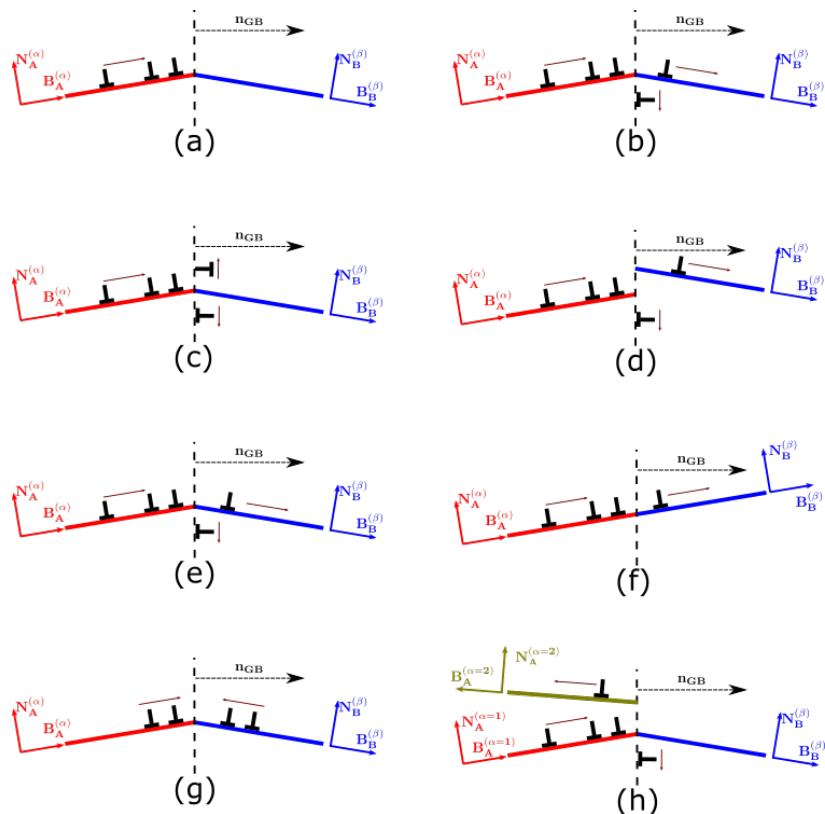
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- Dislocation incorporated into the GB structure.
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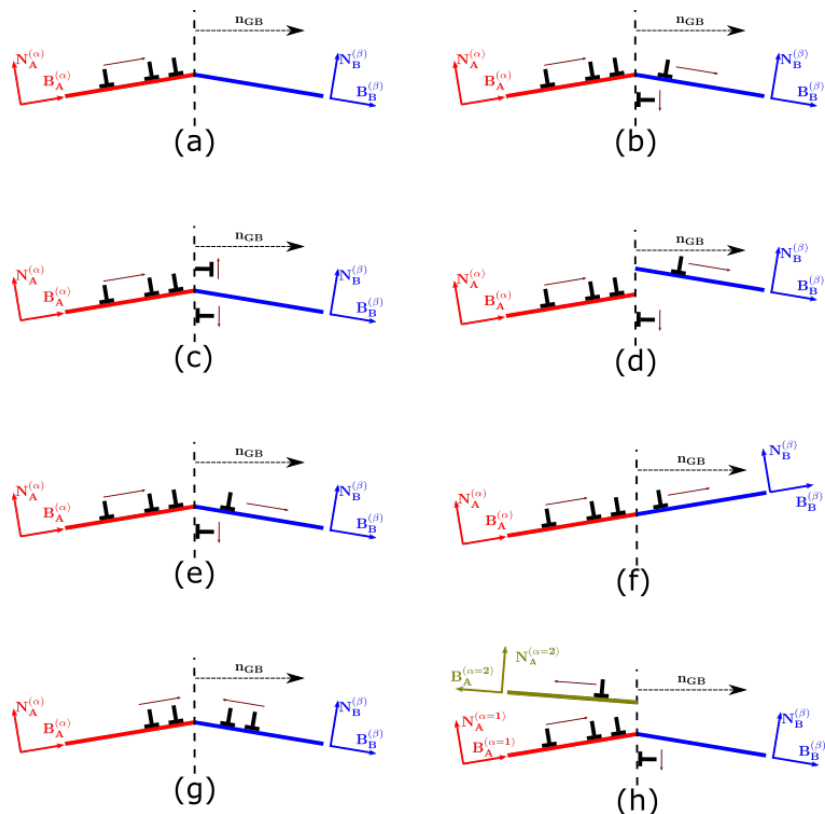
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❖ Mechanical barrier effect

- Grain size controls strength → Hall–Petch relation:

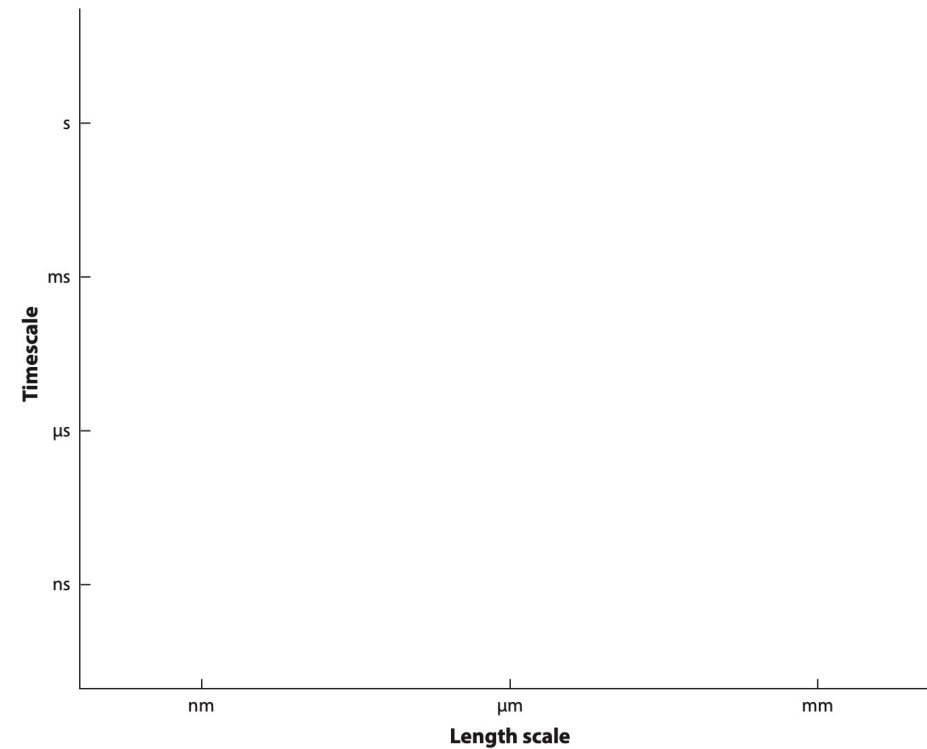
$$\sigma_e = \sigma_0 + Kd^{-\frac{1}{2}}$$

↳ GBs are not passive walls; they block, transmit, absorb, and emit dislocations, ultimately shaping the strength of polycrystals.

Modeling and simulation

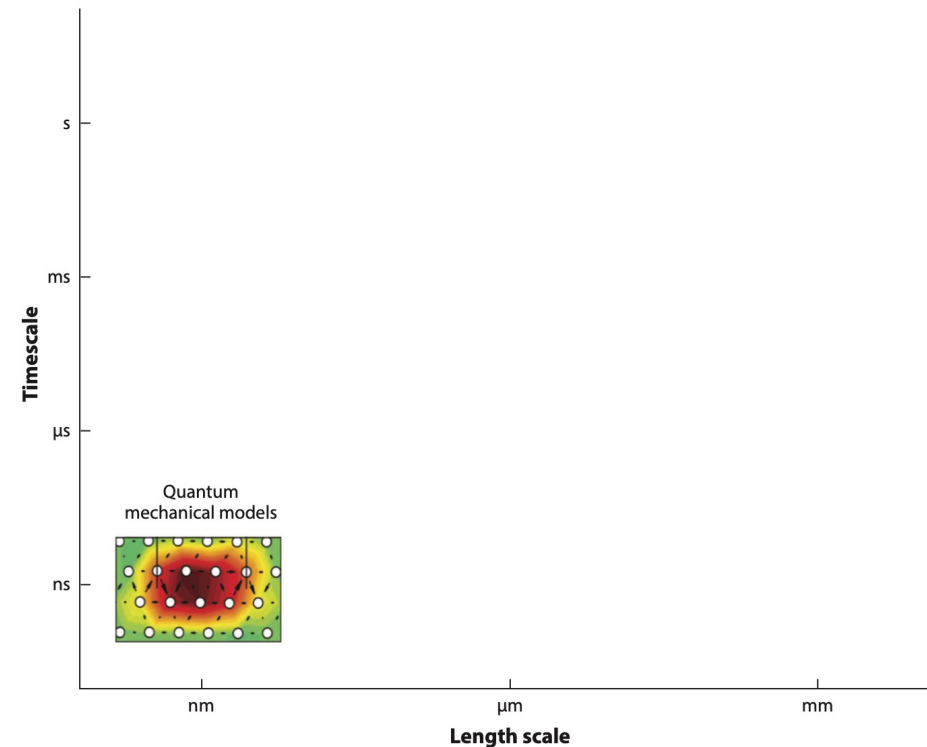
Multiscale modeling of crystal plasticity

- ❖ Dislocation physics spans ~ 9 orders of magnitude in length (nm $\rightarrow$ mm) and ~ 12 orders of magnitude in time (ns $\rightarrow$ s).



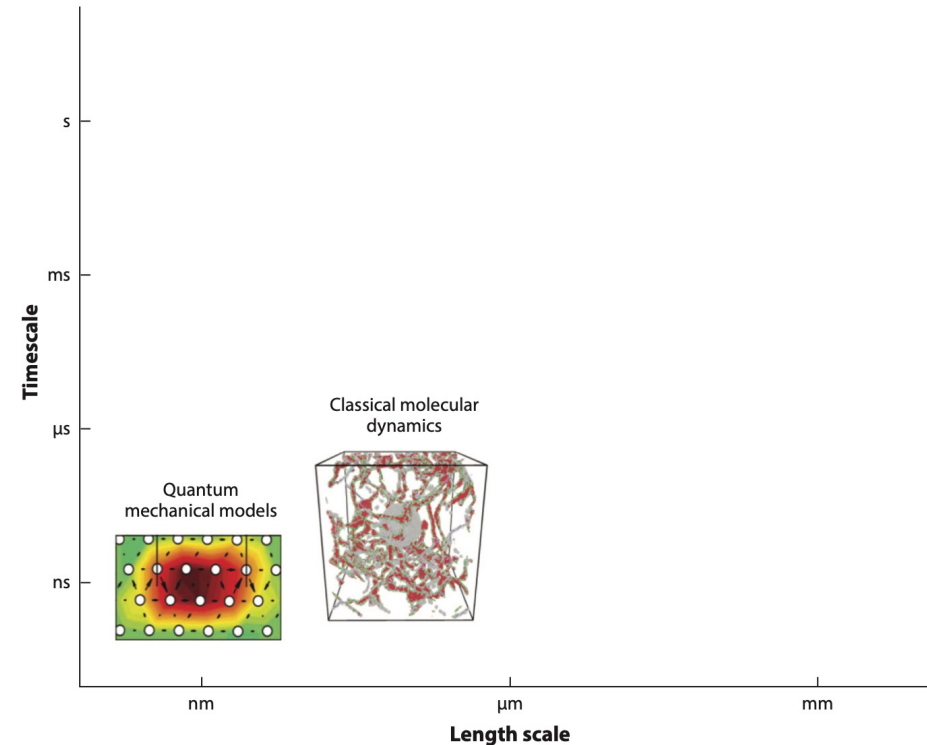
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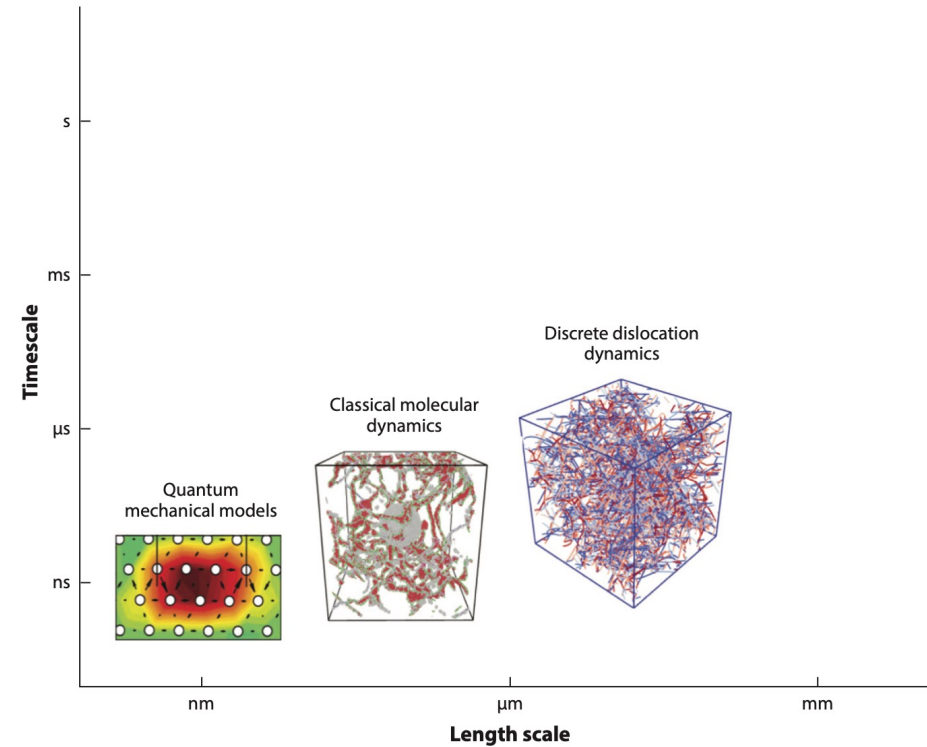
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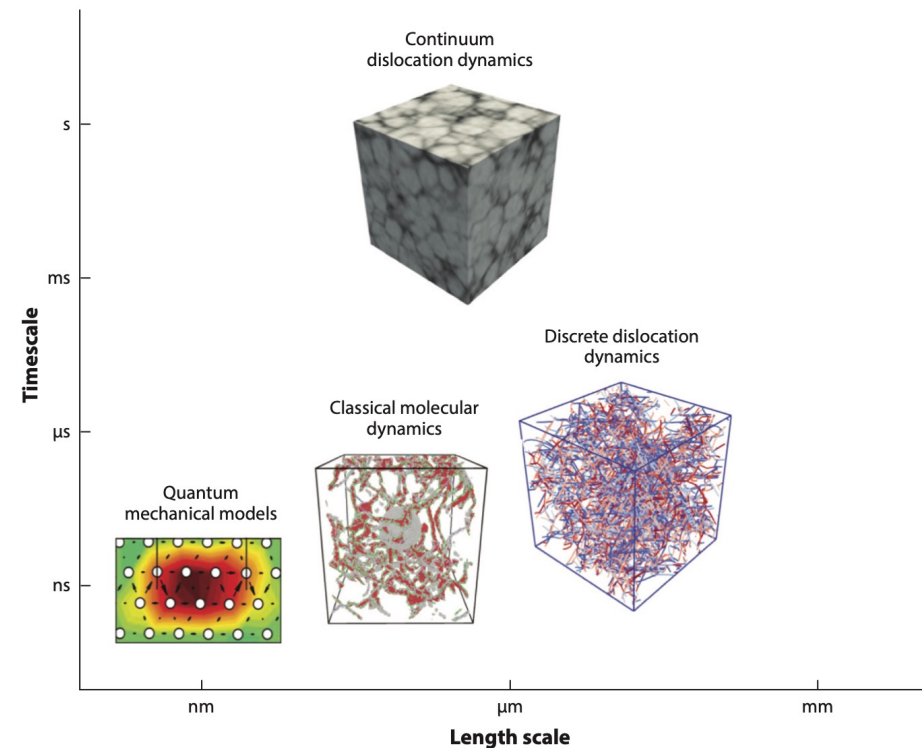
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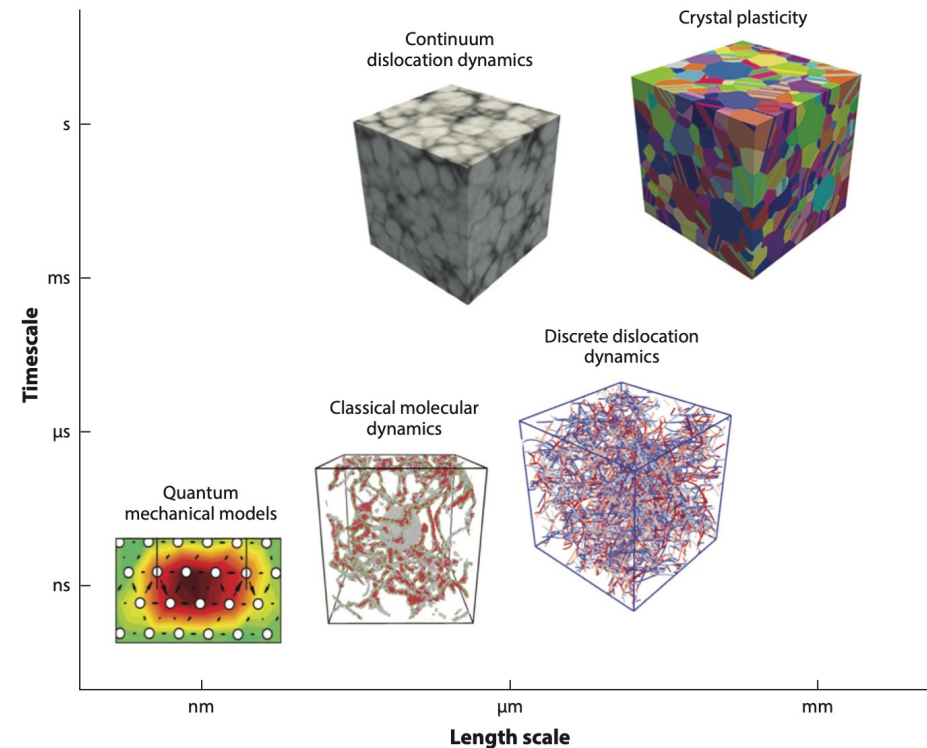
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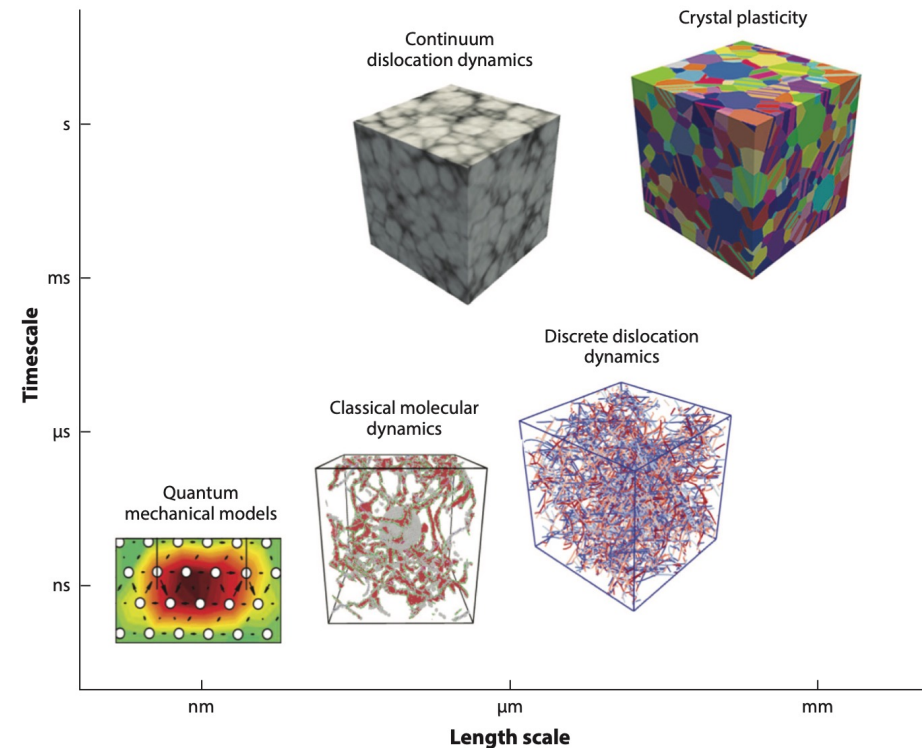
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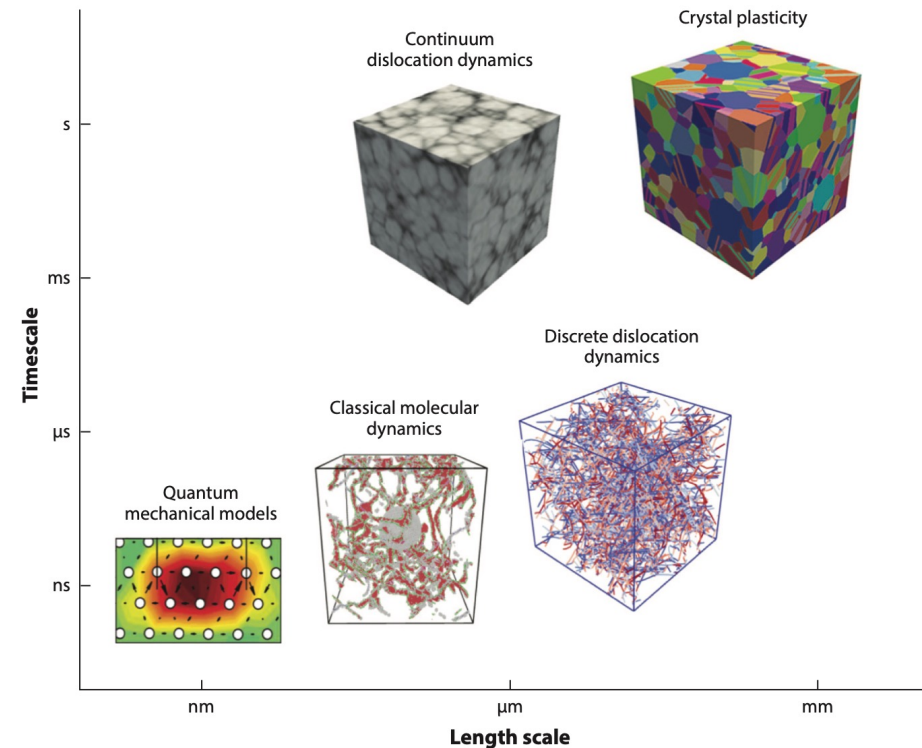
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 - Finite element method (FEM): structural response, component-scale deformation, coupling with CP constitutive laws ($\sim$ mm $\rightarrow$ m, $\sim$ s)



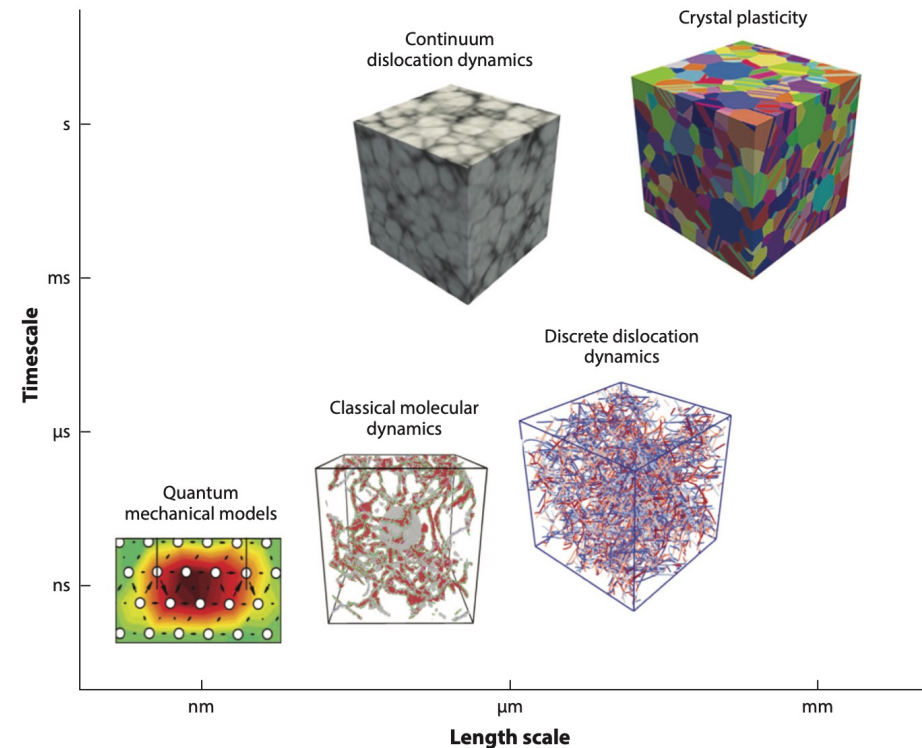
Multiscale modeling of crystal plasticity

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- ❖ No single method covers this range; each tool is optimized for a specific window:
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 - Molecular dynamics (MD): dislocation mobility, cross-slip, nucleation (~ 10 - 100 nm, $\sim$ ns)
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- ❖ The multiscale framework passes information upward (upscaling) and uses higher-scale boundary conditions to regulate lower-scale models.



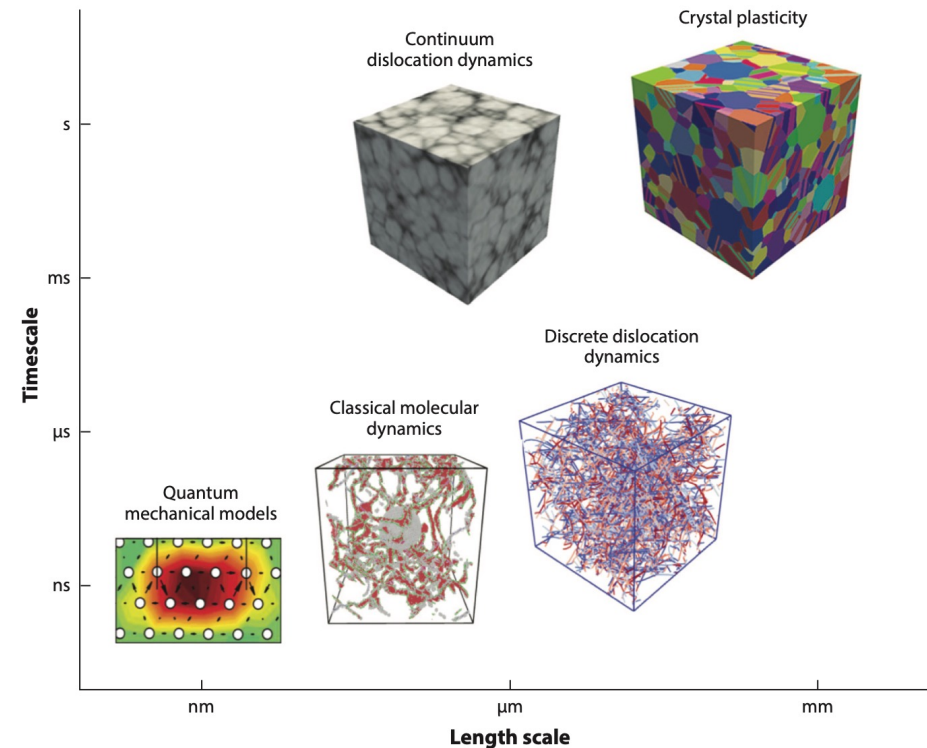
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↪ Bridging these scales remains the central challenge of computational crystal plasticity.



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Thanks for your listening!

If you need further information:

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